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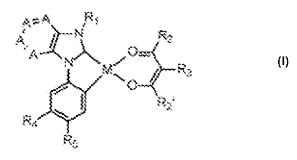
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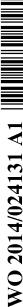
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(54) Title: TRANSITION METAL COMPLEXES WITH CARBENE LIGANDS AND USE THEREOF IN OLEDS



(57) Abstract: The palladium and platinum complexes with one bidentate carbene ligand have the general formula (I). The OLEDs (Organic Light-Emitting Diodes) comprise the said complexes. A device selected from the group consisting of illuminating elements, stationary units and mobile visual display units comprises the said OLEDs. The use of such a metal-carbene complex in OLEDs, for example as emitter, matrix material, charge transport material and/or charge or exciton blocker.





WO 2014/024131 PCT/IB2013/056434

TRANSITION METAL COMPLEXES WITH CARBENE LIGANDS AND USE THEREOF IN OLEDS

Description

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The present invention relates to palladium and platinum complexes with one bidentate carbene ligand, to OLEDs (Organic Light-Emitting Diodes) which comprise such complexes, to a device selected from the group consisting of illuminating elements, stationary visual display units and mobile visual display units comprising such an OLED, to the use of such a metal-carbene complex in OLEDs, for example as emitter, matrix material, charge transport material and/or charge or exciton blocker.

Organic light-emitting diodes (OLEDs) exploit the propensity of materials to emit light when they are excited by electrical current. OLEDs are of particular interest as an alternative to cathode ray tubes and liquid-crystal displays for production of flat visual display units. Owing to the very compact design and the intrinsically low power consumption, devices comprising OLEDs are suitable especially for mobile applications, for example for applications in cellphones, smartphones, digital cameras, mp3 players, laptops, etc. In addition, white OLEDs give great advantages over the illumination technologies known to date, especially a particularly high efficiency.

The prior art proposes numerous materials which emit light on excitation by electrical current.

25 US2005/0260448 relates to luminescent metal complexes having carbene ligands.

US2006/0024522 discloses the use of transition metal complexes comprising at least one carbene ligand in OLEDs. According to US2006/0024522, these complexes include heteroleptic platinum complexes with a carbene ligand. However, no examples and advantages of complexes of this type have been described.

WO2006/018292 discloses the use of transition metal-carbene complexes having at least one unsymmetrically substituted carbene ligand in organic light-emitting diodes. The complexes are embedded in a polymer matrix.

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WO2007/088093 discloses the synthesis of metal carbene complexes, including one

specific example for a platinum complex:

JP 2008/147398 and JP2008/147424 describe complexes with carbene ligands used in OLEDs.

US2010/0270915 discloses heteroleptic Pt complexes with a substituted acetylacetonato ligand. When used as emissive materials those compounds show a strong dependency of the color on the doping concentration resulting from strong aggregation even at for OLEDs relevant doping concentrations.

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WO2011/073149 discloses Pt complexes having carbene ligands and acetylacetonato derived ligands. However, the carbene ligands of WO2011073149 differ from those in this application. Unlike the complexes of the current invention those complexes are not designed for a deep blue photoluminescence (see example EM15 reported in WO2011/073149: 2% EM15 in PMMA; $\lambda_{max} = 484$ nm).

US provisional application 61/496646 (european patent application number 11169895.7) discloses the use transition metal complexes containing carbene ligands in OLEDs. Besides Ir also Pt is described to be a suitable metal center for those compounds. However, no explicit synthetic example is reported in US provisional application 61/496646.

20 Even though there are already known Pd and Pt carbene complexes which are suitable for use in OLEDs, especially as light-emitting substances, it is desirable to provide more stable and/or more efficient compounds which are usable in industry.

It is therefore an object of the present invention to provide palladium and platinum complexes which are suitable for use in organic electronic components. More particularly, the palladium and platinum complexes shall be suitable for use in OLEDs as emitters, matrix material, charge transport material, or charge blockers. The complexes shall be particularly suitable for color-tuning of the electroluminescence, which enables, for example, the production of full-color displays and white OLEDs. It is a further object of the present invention to provide corresponding complexes which can be used as a mixture with a host compound (matrix material) or as a pure layer as a light-emitting layer in OLEDs. More particularly, it is desirable to provide Pd and Pt transition metal complexes which exhibit a spectrum of properties improved over known Pd or Pt complexes, for example improved efficiencies, improved CIE color coordinates, decreased color dependency on the emitter doping concentration and/or improved lifetime/stability.

Surprisingly, it was found that these objects are achieved in accordance with the invention by metal-carbene complex of the general formula

$$A = A$$

$$A =$$

(I), wherein

M is Pd or Pt,

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R₁ is a linear or branched alkyl radical optionally interrupted by at least one heteroatom, optionally bearing at least one functional group and having 1 to 20 carbon atoms, substituted or unsubstituted cycloalkyl radical optionally interrupted by at least one heteroatom, optionally bearing at least one functional group and having 3 to 20 carbon atoms, substituted or unsubstituted aryl radical, optionally bearing at least one functional group and having 6 to 30 carbon atoms, substituted or unsubstituted heteroaryl radical optionally interrupted by at least one heteroatom, optionally bearing at least one functional group and having a total of 5 to 18 carbon atoms and/or heteroatoms,

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R₂ and R₂' are independently of each other a linear or branched alkyl radical having 1 to 6 carbons atoms, preferably methyl, ethyl, isopropyl, or tert-butyl; substituted or unsubstituted cycloalkyl radical having 3 to 20 carbon atoms, substituted or unsubstituted aryl radical having 6 to 20 carbon atoms, preferably unsubstituted phenyl, 2,6-dialkylphenyl or 2,4,6-trialkylphenyl; substituted or unsubstituted heteroaryl radical having a total of 5 to 18 carbon atoms and/or heteroatoms,

R₃ is hydrogen, a linear or branched alkyl radical having 1 to 6 carbon atoms, substituted or unsubstituted aryl radical having 6 to 20 carbon atoms,

 R_4 and R_5 are independently of each other hydrogen, a linear or branched alkyl radical optionally interrupted by at least one heteroatom, optionally bearing at least one functional group and having 1 to 6 carbon atoms, substituted or unsubstituted cycloalkyl radical optionally interrupted by at least one heteroatom, optionally bearing at least one functional group and having 3 to 12 carbon atoms, substituted or unsubstituted aryl radical optionally interrupted by at least one heteroatom, optionally bearing at least one functional group and having 6 to 15 carbon atoms, substituted or unsubstituted heteroaryl radical optionally interrupted by at least one heteroatom, optionally bearing at least one functional group and having a total of 5 to 18 carbon atoms and/or heteroatoms, group with donor or acceptor action,

A is independently in each occurrence CR_6 or N, with the proviso that at least 3 As are CR_6 ; each R_6 is independently of each other hydrogen, a linear or branched alkyl radical optionally interrupted by at least one heteroatom, optionally bearing at least one functional group and having 1 to 20 carbon atoms, substituted or unsubstituted cycloalkyl radical optionally interrupted by at least one heteroatom, optionally bearing at least one functional group and having 3 to 20 carbon atoms, substituted or unsubstituted aryl radical optionally interrupted by at least one heteroatom, optionally bearing at least one functional group and having 6 to 30 carbon atoms, substituted or unsubstituted heteroaryl radical optionally interrupted by at least one heteroatom, optionally bearing at least one functional group and

having a total of 5 to 18 carbon atoms and/or heteroatoms, group with donor or acceptor action.

The inventive metal-carbene complexes can be used in electronic devices, especially OLEDs (Organic Light-Emitting Diodes), for example, as emitter, matrix material, charge transport material and/or charge or exciton blocker.

The inventive metal-carbene complexes are generally notable for light emission in a wide range of the electromagnetic spectrum having a low concentration dependency of the emission spectrum.

The inventive metal-carbene complexes are therefore suitable with particular preference as emitter material in OLEDs.

15 In a preferred embodiment the present invention is directed to metal-carbene complexes of

$$R_{6}$$
 R_{6}
 R_{1}
 R_{2}
 R_{2}
 R_{3}

the general formula

10

(II), wherein

 $R_{6'}$ and $R_{6''}$ have independently of each other the meaning of R_6 and $M,\,R_1,\,R_2,\,R_2'$, $R_3,\,R_4,\,R_5,\,R_6$ and A are each as defined above.

20 In said embodiment metal-carbene complexes of the general formula

$$R_{6}$$
 R_{6}
 R_{1}
 R_{2}
 R_{2}
 R_{4}
 R_{5}

(IIa), or

$$R_{6}$$
 R_{6}
 R_{1}
 R_{2}
 R_{2}
 R_{3}

(IIb) are more preferred, wherein M, R₁, R₂, R₂,

 $R_3,\,R_4,\,R_5,\,R_{6,}\,R_{6'}\,$, $R_{6''}\,$ and A are each as defined above.

M is Pd or Pt, preferably Pt.

 R_5

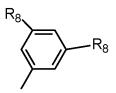
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A is especially CH, or N; very especially CH.

R₁ is preferably a linear or branched alkyl radical having 1 to 6 carbons atoms, very especially methyl, ethyl, isopropyl, tert-butyl; a substituted; or unsubstituted aryl radical having 6 to 15 carbon atoms, especially unsubstituted phenyl, 2,6-dialkylphenyl, or

2,4,6-trialkylphenyl. More preferred R₁ is C₁-C₆alkyl, phenyl,



, wherein R₈ is C₁-C₄alkyl and R₈ is H, or C₁-C₄alkyl;



, wherein R_9 is H, CF_3 , C_1 - C_6 alkyl, F, or $Si(CH_3)_3$. Most preferred R^1 is unsubstituted phenyl, 2,6-diC₁- C_6 alkylphenyl, or 2,4,6-triC₁- C_6 alkylphenyl.

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Preferably R_2 and R_2 ' are independently of each other a linear or branched alkyl radical having 1 to 6 carbon atoms, a substituted or unsubstituted aryl radical having 6 to 20 carbon atoms, preferably unsubstituted phenyl, 2,6-dialkylphenyl or 2,4,6-trialkylphenyl; substituted or unsubstituted heteroaryl radical having a total of 5 to 18 carbon atoms and/or heteroatoms. In a preferred embodiment of the present invention at least one of R_2 and

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$$R_7$$
 R_7

 $R_2{'}$, especially R_2 and $R_2{'}$ are phenyl, or a group of formula R_7 is $C_1\hbox{-} C_6$ alkyl and $R_7{'}$ is hydrogen, or $C_1\hbox{-} C_6$ alkyl.

, wherein

R₃ is preferably hydrogen, or a linear or branched alkyl radical having 1 to 6 carbon atoms, more preferably hydrogen.

$$R_2$$

Examples of suitable compounds HL,

, from which the ligands L,

are derived, include

(2,4-pentanedione [acac]),

(2,2,6,6-tetramethyl-3,5-heptanedione [TMH]),

(1,3-diphenyl-1,3-propanedione [DI]),

(4,4,4-trifluoro-1-(2-thienyl)-1,3-butanedione

[TTFA]),

(7,7-dimethyl-1,1,1,2,2,3,3-heptafluoro-4,6-octanedione

[FOD]),

5

Preferably, R₄ and R₅ are each independently hydrogen, a linear or branched alkyl radical having 1 to 6 carbon atoms, substituted or unsubstituted aryl radical having 6 to 15 carbon atoms, or a group with donor or acceptor action, selected from halogen radicals, preferably F and Cl, more preferably F; CF₃, CN and SiMe₃. Most preferred, R₄ is H, CF₃, C₁-C₆alkyl, F, or Si(CH₃)₃. Most preferred, R₅ is H, CF₃, C₁-C₆alkyl, F, or Si(CH₃)₃.

10 R_6 and $R_{6'}$ are especially hydrogen, or C_1 - C_6 alkyl, very especially H. $R_{6''}$ is preferably hydrogen.

In a particularly preferred embodiment the present invention is directed to metal-carbene

$$R_{6}$$
 R_{6}
 R_{7}
 R_{7}
 R_{7}
 R_{7}
 R_{7}
 R_{7}
 R_{7}
 R_{7}
 R_{7}
 R_{7}

complexes of formula

(III), wherein

R₁ is a linear or branched alkyl radical having 1 to 6 carbons atoms, preferably methyl, ethyl, isopropyl, tert-butyl; a substituted, or unsubstituted aryl radical having 6 to 15 carbon atoms, preferably unsubstituted phenyl, 2,6-dialkylphenyl, or 2,4,6-trialkylphenyl,

 R_4 and R_5 are each independently hydrogen, a linear or branched alkyl radical having 1 to 6 carbon atoms, substituted or unsubstituted aryl radical having 6 to 15 carbon atoms, or a group with donor or acceptor action, selected from halogen radicals, preferably F and Cl, more preferably F; CF_3 , CN and $SiMe_3$,

 R_6 and $R_{6'}$ are each independently hydrogen, a linear or branched alkyl radical, preferably H, methyl, ethyl, isopropyl, or tert-butyl;

R₆" is hydrogen;

20

25 R₇ is a linear or branched alkyl radical having 1 to 6 carbons atoms, a substituted or unsubstituted cycloalkyl radical having 3 to 6 carbon atoms, preferably methyl, ethyl, isopropyl, tert-butyl; and

 $R_{7'}$ is H, or has the meaning of $R_{7.}$

R₁ is preferably a linear or branched alkyl radical having 1 to 6 carbons atoms, very especially methyl, ethyl, isopropyl, tert-butyl; a substituted; or unsubstituted aryl radical having 6 to 15 carbon atoms, very especially unsubstituted phenyl, 2,6-dialkylphenyl, or 2,4,6-trialkylphenyl.

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Preferably, R₆ and R₆ are hydrogen, or C₁-C₆alkyl; and R₆ is hydrogen.

Examples of C_1 - C_6 alkyl are methyl, ethyl, propyl, isopropyl, butyl, isobutyl, isopentyl, sec-butyl, tert-butyl, pentyl, neopentyl and hexyl.

10 In a preferred embodiment the present invention is directed to compounds of formula

, wherein

M is Pd or Pt, preferably Pt;

A is CH, or N;

$$R_8$$
 R_8
 R_8

R₁ is C₁-C₄alkyl, phenyl,

, wherein R₈ is C₁-C₄alkyl

wherein R₇ is

$$R_9$$

15 and R_8 is H, or C_1 - C_4 alkyl; F, or $Si(CH_3)_3$;

, wherein R₉ is H, CF₃, C₁-C₄alkyl,

$$R_7$$
 R_7

 R_2 and R_{2^\prime} $\,$ are $C_1\text{-}C_6\text{alkyl},$ phenyl, or a group of formula

 C_1 - C_4 alkyl and R_7 is H, or C_1 - C_4 alkyl;

R₃ is hydrogen;

 $20 \qquad R_4 \, is \, H, \, CF_3, \, C_1\text{-}C_4 alkyl, \, F, \, or \, Si(CH_3)_3;$

 R_5 is H, CF_3 , C_1 - C_4 alkyl, F, or $Si(CH_3)_3$;

R₆ and R₆ are hydrogen; and

R_{6"} is hydrogen.

 C_1 - C_4 alkyl is methyl, ethyl, propyl, isopropyl, butyl, isobutyl, isopentyl, sec-butyl, or tert-butyl, especially methyl, ethyl, isopropyl, or tert-butyl.

5 Examples of suitable compounds are shown in the table below:

$$R_1$$
 R_2
 R_4
 R_5
 R_1
 R_2
 R_2

Cpd.	R ₁	R ₂	R ₄	R ₅	Α
D-1	Me	Me	Н	Н	СН
D-2	Me	Me	tBu	Н	СН
D-3	Me	Me	SiMe ₃	Н	СН
D-4	Me	Me	CF ₃	Н	СН
D-5	Me	Me	F	Н	СН
D-6	Me	Me	Н	tBu	СН
D-7	Me	Me	Н	SiMe ₃	СН
D-8	Me	Me	Н	CF ₃	СН
D-9	Me	Me	Н	F	СН
D-10	Me	Me	Н	CN	СН
D-11	Me	tBu	Н	Н	СН
D-12	Me	tBu	tBu	Н	СН
D-13	Me	tBu	SiMe ₃	Н	СН
D-14	Me	tBu	CF ₃	Н	СН
D-15	Me	tBu	F	Н	СН
D-16	Me	tBu	Н	tBu	СН
D-17	Me	tBu	Н	SiMe ₃	СН
D-18	Me	tBu	Н	CF ₃	СН
D-19	Me	tBu	Н	F	СН
D-20	Me	tBu	Н	CN	СН
D-21	Me	Ph	Н	Н	СН
D-22	Me	Ph	tBu	Н	СН
D-23	Me	Ph	SiMe₃	Н	СН
D-24	Me	Ph	CF ₃	Н	СН
D-25	Me	Ph	F	Н	СН
D-26	Me	Ph	Н	tBu	СН
D-27	Me	Ph	Н	SiMe ₃	СН
D-28	Me	Ph	Н	CF ₃	СН
D-29	Me	Ph	Н	F	СН

D-30	Me	Ph	Н	CN	СН
D-31	Me	DIPP	Н	Н	СН
D-32	Me	DIPP	tBu	Н	СН
D-33	Me	DIPP	SiMe₃	Н	СН
D-34	Me	DIPP	CF ₃	Н	СН
D-35	Me	DIPP	F	Н	СН
D-36	Me	DIPP	Н	tBu	СН
D-37	Me	DIPP	Н	SiMe ₃	СН
D-38	Me	DIPP	Н	CF ₃	СН
D-39	Me	DIPP	Н	F	СН
D-40	Me	DIPP	Н	CN	СН
D-41	Me	TMP	Н	Н	СН
D-42	Me	TMP	tBu	Н	СН
D-43	Me	TMP	SiMe₃	Н	СН
D-44	Me	TMP	CF ₃	Н	СН
D-45	Me	TMP	F	Н	СН
D-46	Me	TMP	Н	tBu	СН
D-47	Me	TMP	Н	SiMe ₃	CH
D-48	Me	TMP	Н	CF ₃	СН
D-49	Me	TMP	Н	F	СН
D-50	Me	TMP	Н	CN	СН
D-51	iPr	Me	Н	Н	СН
D-52	iPr	Me	tBu	Н	СН
D-53	iPr	Me	SiMe₃	Н	СН
D-55	iPr	Me	CF₃	Н	СН
D-56	iPr	Me	F	Н	СН
D-57	iPr	Me	Н	tBu	СН
D-58	iPr	Me	Н	SiMe ₃	СН
D-59	iPr	Me	Н	CF ₃	СН
D-60	iPr	Me	Н	F	СН
D-61	iPr	Me	Н	CN	СН
D-62	iPr	tBu	Н	Н	СН
D-63	iPr	tBu	tBu	Н	СН
D-64	iPr	tBu	SiMe ₃	Н	CH
D-65	iPr	tBu	CF ₃	Н	CH
D-66	iPr	tBu	F	Н	СН
D-67	iPr	tBu	Н	tBu	СН
D-68	iPr	tBu	Н	SiMe ₃	СН
D-69	iPr	tBu	Н	CF ₃	СН
D-70	iPr	tBu	Н	F	СН
D-71	iPr	tBu	Н	CN	СН
D-72	iPr	Ph	Н	Н	СН
D-73	iPr	Ph	tBu	Н	СН

D-74 iPr Ph SiMe₃				11		
D-76 IPr Ph F H CH D-77 IPr Ph H tBu CH D-78 IPr Ph H SIMe₃ CH D-79 IPr Ph H CF₃ CH D-80 IPr Ph H F CH D-81 IPr DIPP Ph H CH D-81 IPr DIPP Ph H CH D-81 IPr DIPP Ph H CH D-82 IPr DIPP H H CH D-83 IPr DIPP BH H CH D-84 IPr DIPP BW H CH D-85 IPr DIPP DIPP F H CH D-86 IPr DIPP H BBu CH CH D-80 IPr DIPP DIPP H F CH </td <td>D-74</td> <td>iPr</td> <td>Ph</td> <td>SiMe₃</td> <td>Н</td> <td>СН</td>	D-74	iPr	Ph	SiMe₃	Н	СН
D-77 IPr Ph H IBu CH D-78 iPr Ph H SiMe₃ CH D-79 iPr Ph H CF₃ CH D-80 iPr Ph H F CH D-81 iPr PP Ph H CH D-82 iPr DIPP H H CH D-83 iPr DIPP H H CH D-83 iPr DIPP Bu H CH D-83 iPr DIPP Bu H CH D-84 iPr DIPP CH CH D-85 iPr DIPP CH CH D-85 iPr DIPP DIPP H Bu CH CH CH D-86 iPr DIPP H Bu CH CH D-98 iPr DIPP DIPP H CF3 CH CH D-99	D-75	iPr	Ph	CF ₃	Н	СН
D-78 iPr Ph H SiMe₃ CH D-79 iPr Ph H CF₃ CH D-80 iPr Ph H F CH D-81 iPr Ph H CN CH D-81 iPr DIPP Ph H CH D-82 iPr DIPP H H CH D-83 iPr DIPP Bu CH CH D-84 iPr DIPP SiMe₃ H CH CH D-85 iPr DIPP CF₃ H CH CH CH D-86 iPr DIPP H CH CH CH D-86 iPr DIPP H Bu CH CH D-96 IPr DIPP H Bu CH CH D-98 IPr DIPP DIPP H CH CH D-99 IPr TMP H CH CH	D-76	iPr	Ph	F	Н	СН
D-79 iPr Ph H CF₃ CH D-80 iPr Ph H F CH D-81 iPr Ph H CN CH D-81 iPr Ph H CN CH D-82 iPr DIPP H H CN CH D-83 iPr DIPP SiMe₃ H CH D-84 iPr DIPP SiMe₃ H CH D-85 iPr DIPP F H CH D-86 iPr DIPP F H CH D-87 iPr DIPP H SiMe₃ CH D-88 iPr DIPP H CF₃ CH D-89 iPr DIPP H CF₃ CH D-90 iPr DIPP H CF₃ CH D-91 iPr DIPP H CN D-92 iPr TMP H CN D-93 iPr TMP CH D-94 iPr TMP CF₃ CH D-95 iPr TMP CH D-96 iPr TMP F H CH D-97 iPr TMP CH D-98 iPr TMP CH D-99 iPr TMP CH D-91 iPr TMP CH D-91 iPr TMP CH D-92 iPr TMP CH D-93 iPr TMP CH D-94 iPr TMP CH D-95 iPr TMP CH D-96 iPr TMP CH D-97 iPr TMP CH D-98 iPr TMP CH D-99 iPr TMP CH D-99 iPr TMP CH D-100 iPr TMP CH D-101 iPr TMP CH D-102 Ph Me CH D-103 3-tBu-Ph Me SiMe₃ CH D-104 3-(Me₃Si)Ph Me SiMe₃ CH D-105 3-(F₃C)Ph Me CF₃ CH D-100 CH D-101 4-tBu-Ph Me CH D-101 4-tBu-Ph Me CH D-102 Ph Me CH D-103 3-tBu-Ph Me CH D-104 4-(Me₃Si)Ph Me CF₃ CH D-105 4-(F₃C)Ph Me CH D-107 4-tBu-Ph Me CH D-108 4-(Me₃Si)Ph Me CH D-109 4-(F₃C)Ph Me CH D-111 4-NC-Ph Me H CN D-112 Ph Bu CH D-113 3-tBu-Ph Bu UBU H CH D-114 3-(Me₃Si)Ph tBu SiMe₃ CH D-115 3-(F₃C)Ph tBu CH D-115 3-(F₃C)Ph tBu CH D-116 CH D-116 3-(F₃C)Ph tBu CH D-116 CH D-117 CH D-118 CH D-118 CH D-116 CH D-116 CH D-116 CH D-116 CH D-117 CH D-118 CH D-1116 CH D-11	D-77	iPr	Ph	Н	tBu	СН
D-80 iPr Ph H F CH D-81 iPr Ph H CN CH D-82 iPr DIPP H H CH D-83 iPr DIPP H H CH D-84 iPr DIPP SIMe₃ H CH D-85 iPr DIPP CF₃ H CH D-86 iPr DIPP F H CH D-87 iPr DIPP H tBu CH D-88 iPr DIPP H SIMe₃ CH D-89 iPr DIPP H F CH D-99 iPr DIPP H F CH D-91 iPr DIPP H CN CH D-92 iPr TMP H H CH D-93 iPr TMP tBu H CH D-94 iP	D-78	iPr	Ph	Н	SiMe ₃	СН
D-81 iPr Ph H CN CH D-82 iPr DIPP H H CH D-83 iPr DIPP tBu H CH D-84 iPr DIPP SIMe₃ H CH D-85 iPr DIPP CF₃ H CH D-86 iPr DIPP F H CH D-87 iPr DIPP F H CH D-87 iPr DIPP H tBu CH D-88 iPr DIPP H tBu CH D-89 iPr DIPP H CF₃ CH D-90 iPr DIPP H F CH D-91 iPr DIPP H CF₃ CH D-91 iPr TMP H H CH D-92 iPr TMP H H CH D-93 <td< td=""><td>D-79</td><td>iPr</td><td>Ph</td><td>Н</td><td>CF₃</td><td>СН</td></td<>	D-79	iPr	Ph	Н	CF ₃	СН
D-82 iPr DIPP H H CH D-83 iPr DIPP tBu H CH D-84 iPr DIPP SiMe₃ H CH D-85 iPr DIPP CF₃ H CH D-86 iPr DIPP F H CH D-87 iPr DIPP H tBu CH D-88 iPr DIPP H SiMe₃ CH D-89 iPr DIPP H CF₃ CH D-90 iPr DIPP H F CH D-91 iPr DIPP H F CH D-91 iPr DIPP H F CH D-92 iPr TMP H H CH D-93 iPr TMP tBu H CH D-94 iPr TMP SiMe₃ H CH D-95	D-80	iPr	Ph	Н	F	СН
D-83 iPr DIPP tBu H CH D-84 iPr DIPP SiMe₃ H CH D-85 iPr DIPP CF₃ H CH D-86 iPr DIPP F H CH D-87 iPr DIPP H tBu CH D-88 iPr DIPP H SiMe₃ CH D-89 iPr DIPP H CF₃ CH D-90 iPr DIPP H F CH D-91 iPr DIPP H F CH D-91 iPr DIPP H CN CH D-92 iPr TMP H H CH D-93 iPr TMP H H CH D-94 iPr TMP SiMe₃ H CH D-95 iPr TMP F H CH D-96	D-81	iPr	Ph	Н	CN	СН
D-84 iPr DIPP SiMe₃ H CH D-85 iPr DIPP CF₃ H CH D-86 iPr DIPP F H CH D-87 iPr DIPP H tBu CH D-87 iPr DIPP H SiMe₃ CH D-87 iPr DIPP H SiMe₃ CH D-84 iPr DIPP H CF₃ CH D-90 iPr DIPP H CF CH D-91 iPr DIPP H CH CH D-92 iPr TMP H H CH D-93 iPr TMP tBu H CH D-93 iPr TMP TMP H CH D-95 iPr TMP F H CH D-96 iPr TMP H tBu CH D-97	D-82	iPr	DIPP	Н	Н	СН
D-85 iPr DIPP CF3 H CH D-86 iPr DIPP F H CH D-87 iPr DIPP H tBu CH D-87 iPr DIPP H tBu CH D-88 iPr DIPP H SiMe3 CH D-89 iPr DIPP H CF3 CH D-90 iPr DIPP H CF3 CH D-90 iPr DIPP H CF3 CH D-91 iPr DIPP H CN CH D-91 iPr TMP H CH CH D-92 iPr TMP H CH CH CH CH D-92 iPr TMP TMP H CH CH CH D-93 iPr TMP TMP F H CH CH D-96 iPr TMP TMP TMP	D-83	iPr	DIPP	tBu	Н	СН
D-86 iPr DIPP F H CH D-87 iPr DIPP H tBu CH D-88 iPr DIPP H SiMe ₃ CH D-89 iPr DIPP H CF ₃ CH D-90 iPr DIPP H F CH D-90 iPr DIPP H F CH D-90 iPr DIPP H F CH D-91 iPr DIPP H F CH D-91 iPr DIPP H CH CH D-92 iPr TMP H H CH CH CH D-93 iPr TMP TMP SiMe ₃ H CH CH D-95 iPr TMP F H CH CH D-95 iPr TMP F H CH CH D-96 iPr TMP F H CH	D-84	iPr	DIPP	SiMe ₃	Н	СН
D-87 iPr DIPP H tBu CH D-88 iPr DIPP H SiMe ₃ CH D-89 iPr DIPP H CF ₃ CH D-90 iPr DIPP H CF ₃ CH D-90 iPr DIPP H F CH D-91 iPr DIPP H F CH D-91 iPr DIPP H CN CH D-91 iPr DIPP H CN CH D-93 iPr TMP H H CH D-94 iPr TMP SiMe ₃ H CH D-95 iPr TMP CF ₃ H CH D-96 iPr TMP F H CH D-97 iPr TMP H tBu CH D-98 iPr TMP H CF ₃ CH D-100 </td <td>D-85</td> <td>iPr</td> <td>DIPP</td> <td>CF₃</td> <td>Н</td> <td>СН</td>	D-85	iPr	DIPP	CF ₃	Н	СН
D-88 iPr DIPP H SiMe₃ CH D-89 iPr DIPP H CF₃ CH D-90 iPr DIPP H F CH D-91 iPr DIPP H F CH D-91 iPr DIPP H CN CH D-92 iPr TMP H H CH D-93 iPr TMP H H CH D-93 iPr TMP SiMe₃ H CH D-94 iPr TMP SiMe₃ H CH D-95 iPr TMP F H CH D-96 iPr TMP F H CH D-97 iPr TMP H Bu CH D-98 iPr TMP H SiMe₃ CH D-99 iPr TMP H F CH D-100	D-86	iPr	DIPP	F	Н	СН
D-89 iPr DIPP H CF₃ CH D-90 iPr DIPP H F CH D-91 iPr DIPP H F CH D-92 iPr TMP H H CH D-93 iPr TMP H H CH D-93 iPr TMP Bu H CH D-94 iPr TMP SiMe₃ H CH D-95 iPr TMP CF₃ H CH D-96 iPr TMP F H CH D-97 iPr TMP H tBu CH D-98 iPr TMP H SiMe₃ CH D-99 iPr TMP H F CH D-100 iPr TMP H F CH D-101 iPr TMP H F CH D-102 Ph <td>D-87</td> <td>iPr</td> <td>DIPP</td> <td>Н</td> <td>tBu</td> <td>СН</td>	D-87	iPr	DIPP	Н	tBu	СН
D-90 iPr DIPP H F CH D-91 iPr DIPP H CN CH D-92 iPr TMP H H CH D-93 iPr TMP tBu H CH D-94 iPr TMP tBu H CH D-95 iPr TMP SiMe₃ H CH D-96 iPr TMP F H CH D-96 iPr TMP F H CH D-97 iPr TMP H tBu CH D-98 iPr TMP H SiMe₃ CH D-99 iPr TMP H CF₃ CH D-100 iPr TMP H F CH D-101 iPr TMP H F CH D-102 Ph Me H H CH D-103 3-tBu	D-88	iPr	DIPP	Н	SiMe ₃	СН
D-91 iPr DIPP H CN CH D-92 iPr TMP H H CH D-93 iPr TMP tBu H CH D-94 iPr TMP tBu H CH D-95 iPr TMP CF₃ H CH D-96 iPr TMP F H CH D-96 iPr TMP F H CH D-97 iPr TMP H tBu CH D-98 iPr TMP H SiMe₃ CH D-99 iPr TMP H CF₃ CH D-100 iPr TMP H F CH D-101 iPr TMP H F CH D-102 Ph Me H H CH D-103 3-tBu-Ph Me tBu H CH D-104 3	D-89	iPr	DIPP	Н	CF ₃	СН
D-92 iPr TMP H H CH D-93 iPr TMP tBu H CH D-94 iPr TMP SiMe₃ H CH D-95 iPr TMP CF₃ H CH D-96 iPr TMP F H CH D-97 iPr TMP H tBu CH D-98 iPr TMP H SiMe₃ CH D-99 iPr TMP H CF₃ CH D-100 iPr TMP H F CH D-100 iPr TMP H F CH D-101 iPr TMP H F CH D-102 Ph Me H H CH D-103 3-tBu-Ph Me tBu H CH D-104 3-(Me₃Si)Ph Me CF₃ H CH D-105	D-90	iPr	DIPP	Н	F	СН
D-93 iPr TMP tBu H CH D-94 iPr TMP SiMe₃ H CH D-95 iPr TMP CF₃ H CH D-96 iPr TMP F H CH D-97 iPr TMP H tBu CH D-98 iPr TMP H SiMe₃ CH D-99 iPr TMP H CF₃ CH D-100 iPr TMP H F CH D-100 iPr TMP H F CH D-101 iPr TMP H F CH D-102 Ph Me H CH CH D-103 3-tBu-Ph Me tBu H CH D-104 3-(Me₃Si)Ph Me SiMe₃ H CH D-105 3-(F₃C)Ph Me F H CH D-10	D-91	iPr	DIPP	Н	CN	СН
D-94 iPr TMP SiMe ₃ H CH D-95 iPr TMP CF ₃ H CH D-96 iPr TMP F H CH D-97 iPr TMP H tBu CH D-98 iPr TMP H SiMe ₃ CH D-99 iPr TMP H CF ₃ CH D-100 iPr TMP H F CH D-101 iPr TMP H F CH D-101 iPr TMP H F CH D-102 Ph Me H CH CH D-103 3-tBu-Ph Me tBu H CH D-104 3-(Fa ₃ C)Ph Me SiMe ₃ H CH D-105 3-(Fa ₃ C)Ph Me F H CH D-106 3-F-Ph Me F H CH	D-92	iPr	TMP	Н	Н	СН
D-95 iPr TMP CF3 H CH D-96 iPr TMP F H CH D-97 iPr TMP H tBu CH D-98 iPr TMP H SiMe3 CH D-99 iPr TMP H CF3 CH D-100 iPr TMP H F CH D-101 iPr TMP H F CH D-101 iPr TMP H F CH D-101 iPr TMP H CN CH D-102 Ph Me H H CH D-103 3-tBu-Ph Me tBu H CH D-104 3-(Me3Si)Ph Me SiMe3 H CH D-105 3-(F3C)Ph Me F H CH D-106 3-F-Ph Me F H CH D-107 </td <td>D-93</td> <td>iPr</td> <td>TMP</td> <td>tBu</td> <td>Н</td> <td>СН</td>	D-93	iPr	TMP	tBu	Н	СН
D-96 iPr TMP F H CH D-97 iPr TMP H tBu CH D-98 iPr TMP H SiMe ₃ CH D-99 iPr TMP H CF ₃ CH D-100 iPr TMP H F CH D-101 iPr TMP H F CH D-101 iPr TMP H CN CH D-101 iPr TMP H CN CH D-102 Ph Me H CH CH D-103 3-tBu-Ph Me tBu H CH D-104 3-(Me ₃ Si)Ph Me SiMe ₃ H CH D-105 3-(F ₃ C)Ph Me F H CH D-106 3-F-Ph Me F H CH D-107 4-tBu-Ph Me H SiMe ₃ CH <tr< td=""><td>D-94</td><td>iPr</td><td>TMP</td><td>SiMe₃</td><td>Н</td><td>СН</td></tr<>	D-94	iPr	TMP	SiMe ₃	Н	СН
D-97 iPr TMP H tBu CH D-98 iPr TMP H SiMe ₃ CH D-99 iPr TMP H CF ₃ CH D-100 iPr TMP H F CH D-101 iPr TMP H CN CH D-101 iPr TMP H CN CH D-101 iPr TMP H CN CH D-102 Ph Me H CH CH D-103 3-tBu-Ph Me tBu H CH D-104 3-(Me ₃ Si)Ph Me SiMe ₃ H CH D-105 3-(F ₃ C)Ph Me F H CH D-106 3-F-Ph Me F H CH D-107 4-tBu-Ph Me H SiMe ₃ CH D-108 4-(Me ₃ Si)Ph Me H CF ₃ CH	D-95	iPr	TMP	CF ₃	Н	СН
D-98 iPr TMP H SiMe ₃ CH D-99 iPr TMP H CF ₃ CH D-100 iPr TMP H F CH D-101 iPr TMP H F CH D-101 iPr TMP H F CH D-102 Ph Me H H CH D-103 3-tBu-Ph Me tBu H CH D-104 3-(Me ₃ Si)Ph Me SiMe ₃ H CH D-105 3-(F ₃ C)Ph Me F H CH D-106 3-F-Ph Me F H CH D-107 4-tBu-Ph Me H tBu CH D-108 4-(Me ₃ Si)Ph Me H SiMe ₃ CH D-109 4-(F ₃ C)Ph Me H F CH D-110 4-F-Ph Me H CN CH	D-96	iPr	TMP	F	Н	СН
D-99 iPr TMP H CF3 CH D-100 iPr TMP H F CH D-101 iPr TMP H CN CH D-102 Ph Me H CH CH D-103 3-tBu-Ph Me tBu H CH D-104 3-(Me3Si)Ph Me SiMe3 H CH D-105 3-(F3C)Ph Me CF3 H CH D-105 3-(F3C)Ph Me F H CH D-106 3-F-Ph Me F H CH D-107 4-tBu-Ph Me H tBu CH D-108 4-(Me3Si)Ph Me H SiMe3 CH D-109 4-(F3C)Ph Me H F CH D-110 4-F-Ph Me H F CH D-111 4-NC-Ph Me H CN CH </td <td>D-97</td> <td>iPr</td> <td>TMP</td> <td>Н</td> <td>tBu</td> <td>СН</td>	D-97	iPr	TMP	Н	tBu	СН
D-100 iPr TMP H F CH D-101 iPr TMP H CN CH D-102 Ph Me H H CH D-103 3-tBu-Ph Me tBu H CH D-104 3-(Me ₃ Si)Ph Me SiMe ₃ H CH D-105 3-(F ₃ C)Ph Me F H CH D-106 3-F-Ph Me F H CH D-107 4-tBu-Ph Me H SiMe ₃ CH D-108 4-(Me ₃ Si)Ph Me H SiMe ₃ CH D-109 4-(F ₃ C)Ph Me H CF ₃ CH D-110 4-F-Ph Me H CF ₃ CH D-111 4-NC-Ph Me H CN CH D-112 Ph tBu H CH D-113 3-tBu-Ph tBu tBu H CH D-114 3-(Me ₃ Si)Ph tBu SiMe ₃ H CH D-115 3-(F ₃ C)Ph tBu CH	D-98	iPr	TMP	Н	SiMe ₃	СН
D-101 iPr TMP H CN CH D-102 Ph Me H H CH D-103 3-tBu-Ph Me tBu H CH D-104 3-(Me ₃ Si)Ph Me SiMe ₃ H CH D-105 3-(F ₃ C)Ph Me CF ₃ H CH D-106 3-F-Ph Me F H CH D-106 3-F-Ph Me H tBu CH D-107 4-tBu-Ph Me H tBu CH D-108 4-(Me ₃ Si)Ph Me H SiMe ₃ CH D-109 4-(F ₃ C)Ph Me H CF ₃ CH D-110 4-F-Ph Me H F CH D-111 4-NC-Ph Me H CN CH D-112 Ph tBu H H CH D-113 3-tBu-Ph tBu tBu SiMe ₃	D-99	iPr	TMP	Н	CF ₃	СН
D-102 Ph Me H H CH D-103 3-tBu-Ph Me tBu H CH D-104 3-(Me ₃ Si)Ph Me SiMe ₃ H CH D-105 3-(F ₃ C)Ph Me CF ₃ H CH D-106 3-F-Ph Me F H CH D-107 4-tBu-Ph Me H tBu CH D-107 4-tBu-Ph Me H SiMe ₃ CH D-108 4-(Me ₃ Si)Ph Me H SiMe ₃ CH D-109 4-(F ₃ C)Ph Me H CF ₃ CH D-110 4-F-Ph Me H F CH D-111 4-NC-Ph Me H CN CH D-112 Ph tBu H H CH D-113 3-tBu-Ph tBu tBu H CH D-114 3-(Me ₃ Si)Ph tBu SiMe ₃	D-100	iPr	TMP	Н	F	СН
D-103 3-tBu-Ph Me tBu H CH D-104 3-(Me ₃ Si)Ph Me SiMe ₃ H CH D-105 3-(F ₃ C)Ph Me CF ₃ H CH D-106 3-F-Ph Me F H CH D-107 4-tBu-Ph Me H tBu CH D-108 4-(Me ₃ Si)Ph Me H SiMe ₃ CH D-109 4-(F ₃ C)Ph Me H CF ₃ CH D-110 4-F-Ph Me H F CH D-111 4-NC-Ph Me H CN CH D-112 Ph tBu H H CH D-113 3-tBu-Ph tBu tBu H CH D-114 3-(Me ₃ Si)Ph tBu SiMe ₃ H CH D-115 3-(F ₃ C)Ph tBu CF ₃ H CH	D-101	iPr	TMP	Н	CN	СН
D-104 3-(Me ₃ Si)Ph Me SiMe ₃ H CH D-105 3-(F ₃ C)Ph Me CF ₃ H CH D-106 3-F-Ph Me F H CH D-107 4-tBu-Ph Me H tBu CH D-108 4-(Me ₃ Si)Ph Me H SiMe ₃ CH D-108 4-(F ₃ C)Ph Me H CF ₃ CH D-109 4-(F ₃ C)Ph Me H CF ₃ CH D-110 4-F-Ph Me H F CH D-111 4-NC-Ph Me H CN CH D-112 Ph tBu H H CH D-113 3-tBu-Ph tBu tBu H CH D-114 3-(F ₃ C)Ph tBu CF ₃ H CH D-115 3-(F ₃ C)Ph tBu CF ₃ H CH	D-102	Ph	Me	Н	Н	СН
D-105 3-(F ₃ C)Ph Me CF ₃ H CH D-106 3-F-Ph Me F H CH D-107 4-tBu-Ph Me H tBu CH D-108 4-(Me ₃ Si)Ph Me H SiMe ₃ CH D-109 4-(F ₃ C)Ph Me H CF ₃ CH D-110 4-F-Ph Me H F CH D-111 4-NC-Ph Me H CN CH D-112 Ph tBu H H CH D-113 3-tBu-Ph tBu tBu H CH D-114 3-(Me ₃ Si)Ph tBu SiMe ₃ H CH D-115 3-(F ₃ C)Ph tBu CF ₃ H CH	D-103	3-tBu-Ph	Me	tBu	Н	СН
D-106 3-F-Ph Me F H CH D-107 4-tBu-Ph Me H tBu CH D-108 4-(Me ₃ Si)Ph Me H SiMe ₃ CH D-109 4-(F ₃ C)Ph Me H CF ₃ CH D-110 4-F-Ph Me H F CH D-111 4-NC-Ph Me H CN CH D-112 Ph tBu H H CH D-113 3-tBu-Ph tBu tBu H CH D-114 3-(Me ₃ Si)Ph tBu SiMe ₃ H CH D-115 3-(F ₃ C)Ph tBu CF ₃ H CH	D-104	3-(Me ₃ Si)Ph	Me	SiMe ₃	Н	СН
D-107 4-tBu-Ph Me H tBu CH D-108 4-(Me ₃ Si)Ph Me H SiMe ₃ CH D-109 4-(F ₃ C)Ph Me H CF ₃ CH D-110 4-F-Ph Me H F CH D-111 4-NC-Ph Me H CN CH D-112 Ph tBu H H CH D-113 3-tBu-Ph tBu tBu H CH D-114 3-(Me ₃ Si)Ph tBu SiMe ₃ H CH D-115 3-(F ₃ C)Ph tBu CF ₃ H CH	D-105	3-(F ₃ C)Ph	Me	CF ₃	Н	СН
D-108 4-(Me ₃ Si)Ph Me H SiMe ₃ CH D-109 4-(F ₃ C)Ph Me H CF ₃ CH D-110 4-F-Ph Me H F CH D-111 4-NC-Ph Me H CN CH D-112 Ph tBu H H CH D-113 3-tBu-Ph tBu tBu H CH D-114 3-(Me ₃ Si)Ph tBu SiMe ₃ H CH D-115 3-(F ₃ C)Ph tBu CF ₃ H CH	D-106	3-F-Ph	Me	F	Н	СН
D-109 4-(F ₃ C)Ph Me H CF ₃ CH D-110 4-F-Ph Me H F CH D-111 4-NC-Ph Me H CN CH D-112 Ph tBu H H CH D-113 3-tBu-Ph tBu tBu H CH D-114 3-(Me ₃ Si)Ph tBu SiMe ₃ H CH D-115 3-(F ₃ C)Ph tBu CF ₃ H CH	D-107	4-tBu-Ph	Me	Н	tBu	СН
D-110 4-F-Ph Me H F CH D-111 4-NC-Ph Me H CN CH D-112 Ph tBu H H CH D-113 3-tBu-Ph tBu tBu H CH D-114 3-(Me ₃ Si)Ph tBu SiMe ₃ H CH D-115 3-(F ₃ C)Ph tBu CF ₃ H CH	D-108	4-(Me ₃ Si)Ph	Me	Н	SiMe ₃	СН
D-111 4-NC-Ph Me H CN CH D-112 Ph tBu H H CH D-113 3-tBu-Ph tBu tBu H CH D-114 3-(Me ₃ Si)Ph tBu SiMe ₃ H CH D-115 3-(F ₃ C)Ph tBu CF ₃ H CH	D-109	4-(F ₃ C)Ph	Me	Н	CF ₃	СН
D-112 Ph tBu H H CH D-113 3-tBu-Ph tBu tBu H CH D-114 3-(Me ₃ Si)Ph tBu SiMe ₃ H CH D-115 3-(F ₃ C)Ph tBu CF ₃ H CH	D-110	4-F-Ph	Me	Н	F	СН
D-113 3-tBu-Ph tBu tBu H CH D-114 3-(Me ₃ Si)Ph tBu SiMe ₃ H CH D-115 3-(F ₃ C)Ph tBu CF ₃ H CH	D-111	4-NC-Ph	Me	Н	CN	СН
D-114 3-(Me ₃ Si)Ph tBu SiMe ₃ H CH D-115 3-(F ₃ C)Ph tBu CF ₃ H CH	D-112	Ph	tBu	Н	Н	СН
D-115 3-(F ₃ C)Ph tBu CF ₃ H CH	D-113	3-tBu-Ph	tBu	tBu	Н	СН
	D-114	3-(Me ₃ Si)Ph	tBu	SiMe ₃	Н	СН
D-116 3-F-Ph tBu F H CH	D-115	3-(F ₃ C)Ph	tBu	CF ₃	Н	СН
	D-116	3-F-Ph	tBu	F	Н	СН

D-118 4- D-119 4 D-120 D-121 4 D-122 D-123 3 D-124 3- D-125 3 D-126	4-tBu-Ph -(Me ₃ Si)Ph -(F ₃ C)Ph 4-F-Ph 4-NC-Ph Ph 3-tBu-Ph -(Me ₃ Si)Ph 3-(F ₃ C)Ph 3-F-Ph 4-tBu-Ph	tBu tBu tBu tBu Ph Ph Ph Ph	H H H H H SiMe ₃ CF ₃	tBu SiMe ₃ CF ₃ F CN H	CH CH CH CH
D-119 4 D-120 D-121 4 D-122 D-123 3 D-124 3- D-125 3 D-126	I-(F ₃ C)Ph 4-F-Ph 4-NC-Ph Ph 3-tBu-Ph -(Me ₃ Si)Ph 3-(F ₃ C)Ph 3-F-Ph 4-tBu-Ph	tBu tBu tBu Ph Ph Ph	H H H tBu SiMe ₃	CF₃ F CN H	CH CH CH
D-120 D-121 4 D-122 D-123 3- D-124 3- D-125 3 D-126	4-F-Ph 4-NC-Ph Ph 3-tBu-Ph -(Me ₃ Si)Ph 3-(F ₃ C)Ph 3-F-Ph 4-tBu-Ph	tBu tBu Ph Ph Ph Ph	H H H tBu SiMe ₃	F CN H	CH CH CH
D-121	4-NC-Ph Ph 3-tBu-Ph -(Me ₃ Si)Ph 3-(F ₃ C)Ph 3-F-Ph 4-tBu-Ph	tBu Ph Ph Ph Ph	H H tBu SiMe ₃	CN H H	CH CH
D-122 D-123 3 D-124 3- D-125 3 D-126	Ph 3-tBu-Ph -(Me ₃ Si)Ph 3-(F ₃ C)Ph 3-F-Ph 4-tBu-Ph	Ph Ph Ph Ph	H tBu SiMe ₃	H H	СН
D-123 3- D-124 3- D-125 3 D-126	3-tBu-Ph -(Me ₃ Si)Ph 3-(F ₃ C)Ph 3-F-Ph 4-tBu-Ph	Ph Ph Ph	tBu SiMe ₃	Н	
D-124 3- D-125 3 D-126	G-(Me ₃ Si)Ph B-(F ₃ C)Ph 3-F-Ph 4-tBu-Ph	Ph Ph	SiMe ₃		CLI
D-125 3 D-126	3-(F ₃ C)Ph 3-F-Ph 4-tBu-Ph	Ph			СН
D-126	3-F-Ph 4-tBu-Ph		CF ₃	Н	СН
	4-tBu-Ph	Ph		Н	СН
D-127			F	Η	СН
		Ph	Н	tBu	СН
D-128 4-	·(Me₃Si)Ph	Ph	Н	SiMe₃	СН
D-129 4	l-(F₃C)Ph	Ph	Н	CF ₃	СН
D-130	4-F-Ph	Ph	Н	F	СН
D-131 4	4-NC-Ph	Ph	Н	CN	СН
D-132	Ph	DIPP	Н	Н	СН
D-133	3-tBu-Ph	DIPP	tBu	Н	СН
D-134 3-	·(Me₃Si)Ph	DIPP	SiMe ₃	Н	СН
D-135 3	3-(F ₃ C)Ph	DIPP	CF ₃	Н	СН
D-136	3-F-Ph	DIPP	F	Н	СН
D-137	4-tBu-Ph	DIPP	Н	tBu	СН
D-138 4-	·(Me₃Si)Ph	DIPP	Н	SiMe₃	СН
D-139 4	I-(F₃C)Ph	DIPP	Н	CF ₃	СН
D-140	4-F-Ph	DIPP	Н	F	СН
D-141 4	4-NC-Ph	DIPP	Н	CN	СН
D-142	Ph	TMP	Н	Н	СН
D-143	3-tBu-Ph	TMP	tBu	Н	СН
D-144 3-	·(Me₃Si)Ph	TMP	SiMe₃	Н	СН
D-145 3	3-(F₃C)Ph	TMP	CF ₃	Н	СН
D-146	3-F-Ph	TMP	F	Н	СН
D-147	4-tBu-Ph	TMP	Н	tBu	СН
D-148 4-	·(Me₃Si)Ph	TMP	Н	SiMe ₃	СН
D-149 4	I-(F₃C)Ph	TMP	Н	CF ₃	СН
D-150	4-F-Ph	TMP	Н	F	СН
D-151 4	4-NC-Ph	TMP	Н	CN	СН
D-152	TMP	Me	Н	Н	СН
D-153	TMP	Me	tBu	Н	СН
D-154	TMP	Me	SiMe ₃	Н	СН
D-155	TMP	Me	CF ₃	Н	СН
D-156	TMP	Me	F	Н	СН
D-157	TMP	Me	Н	tBu	СН
D-158	TMP	Me	Н	SiMe₃	СН
D-159	TMP	Me	Н	CF ₃	СН

D-161 TI D-162 TI D-163 TI D-164 TI D-165 TI D-166 TI D-167 TI D-168 TI D-169 TI D-170 TI D-171 TI D-172 TI D-173 TI	MP M	Me Me tBu	H H H tBu SiMe ₃ CF ₃ F H H H	F CN H H H H SiMe ₃ CF ₃ F CN	CH C
D-162 TI D-163 TI D-164 TI D-165 TI D-166 TI D-167 TI D-168 TI D-169 TI D-170 TI D-171 TI D-172 TI D-173 TI	MP M	tBu	H tBu SiMe ₃ CF ₃ F H H H	H H H H SiMe ₃ CF ₃	CH CH CH CH CH CH CH CH CH
D-163 TI D-164 TI D-165 TI D-166 TI D-167 TI D-168 TI D-169 TI D-170 TI D-171 TI D-172 TI D-173 TI	MP M	tBu	tBu SiMe ₃ CF ₃ F H H H	H H H tBu SiMe ₃ CF ₃	CH CH CH CH CH CH CH CH
D-164 TI D-165 TI D-166 TI D-167 TI D-168 TI D-169 TI D-170 TI D-171 TI D-172 TI D-173 TI	MP	tBu	SiMe ₃ CF ₃ F H H H	H H H tBu SiMe ₃ CF ₃	CH CH CH CH CH CH
D-165 TI D-166 TI D-167 TI D-168 TI D-169 TI D-170 TI D-171 TI D-172 TI D-173 TI	MP	tBu tBu tBu tBu tBu tBu tBu tBu tPh	CF ₃ F H H H	H H tBu SiMe ₃ CF ₃ F	CH CH CH CH CH
D-166 TI D-167 TI D-168 TI D-169 TI D-170 TI D-171 TI D-172 TI D-173 TI	MP MP MP MP MP MP MP MP MP	tBu tBu tBu tBu tBu tBu tBu tPh	F H H H	H tBu SiMe ₃ CF ₃	CH CH CH CH
D-167 TI D-168 TI D-169 TI D-170 TI D-171 TI D-172 TI D-173 TI	MP MP MP MP MP MP MP MP	tBu tBu tBu tBu tBu Ph	H H H H	tBu SiMe ₃ CF ₃	CH CH CH
D-168 TI D-169 TI D-170 TI D-171 TI D-172 TI D-173 TI	MP MP MP MP MP MP	tBu tBu tBu tBu Ph	H H H	SiMe ₃ CF ₃ F	CH CH CH
D-169 TI D-170 TI D-171 TI D-172 TI D-173 TI	MP MP MP MP MP	tBu tBu tBu Ph	H H H	CF ₃	CH CH
D-170 TI D-171 TI D-172 TI D-173 TI	MP MP MP	tBu tBu Ph	H H	F	СН
D-171 TI D-172 TI D-173 TI	MP MP	tBu Ph	Н		
D-172 TI	MP MP	Ph		CN	4
D-173 TI	MP		1.1		CH
		D:	Н	Η	СН
D-174 TI	NAD	Ph	tBu	Н	СН
''	MP	Ph	SiMe ₃	Н	СН
D-17 5 TI	MP	Ph	CF ₃	Н	СН
D-176 TI	MP	Ph	F	Н	СН
D-177 TI	MP	Ph	Н	tBu	СН
D-178 TI	MP	Ph	Н	SiMe₃	СН
D-179 TI	MP	Ph	Н	CF ₃	СН
D-180 TI	MP	Ph	Н	F	СН
D-181 TI	MP	Ph	Н	CN	СН
D-182 TI	MP	DIPP	Н	Н	СН
D-183 TI	MP	DIPP	tBu	Η	СН
D-184 TI	MP	DIPP	SiMe ₃	Н	СН
D-185 TI	MP	DIPP	CF ₃	Н	СН
D-186 TI	MP	DIPP	F	Н	СН
D-187 TI	MP	DIPP	Н	tBu	СН
D-188 TI	MP	DIPP	Н	SiMe ₃	СН
D-189 TI	MP	DIPP	Н	CF ₃	СН
D-190 TI	MP	DIPP	Н	F	СН
D-191 TI	MP	DIPP	Н	CN	СН
D-192 TI	MP	TMP	Н	Н	СН
D-193 TI	MP	TMP	tBu	Н	СН
D-194 TI	MP	TMP	SiMe ₃	Н	СН
D-195 TI	MP	TMP	CF ₃	Н	СН
D-196 TI	MP	TMP	F	Н	СН
D-197 TI	MP	TMP	Н	tBu	СН
D-198 TI	MP	TMP	Н	SiMe ₃	СН
D-199 TI	MP	TMP	Н	CF ₃	СН
D-200 TI	MP	TMP	Н	F	СН
D-201 TI	MP	TMP	Н	CN	СН
D-202 D	MP	Me	Н	Н	СН

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D-203	DMP	Me	tBu	Н	СН
D-204	DMP	Me	SiMe₃	Н	СН
D-205	DMP	Me	CF ₃	Н	СН
D-206	DMP	Me	F	Н	CH
D-207	DMP	Me	Н	tBu	CH
D-208	DMP	Me	Н	SiMe ₃	CH
D-209	DMP	Me	Н	CF ₃	СН
D-210	DMP	Me	Н	F	CH
D-211	DMP	Me	Н	CN	СН
D-212	DMP	tBu	Н	Н	СН
D-213	DMP	tBu	tBu	Н	СН
D-214	DMP	tBu	SiMe ₃	Н	СН
D-215	DMP	tBu	CF ₃	Н	СН
D-216	DMP	tBu	F	Н	CH
D-217	DMP	tBu	Н	tBu	СН
D-218	DMP	tBu	Н	SiMe ₃	CH
D-219	DMP	tBu	Н	CF ₃	СН
D-220	DMP	tBu	Н	F	СН
D-221	DMP	tBu	Н	CN	СН
D-222	DMP	Ph	Н	Н	СН
D-223	DMP	Ph	tBu	Н	CH
D-224	DMP	Ph	SiMe₃	Н	CH
D-225	DMP	Ph	CF ₃	Н	СН
D-226	DMP	Ph	F	Н	СН
D-227	DMP	Ph	Н	tBu	СН
D-228	DMP	Ph	Н	SiMe ₃	СН
D-229	DMP	Ph	Н	CF ₃	СН
D-230	DMP	Ph	Н	F	СН
D-231	DMP	Ph	Н	CN	СН
D-232	DMP	DIPP	Н	Н	СН
D-233	DMP	DIPP	tBu	Н	СН
D-234	DMP	DIPP	SiMe ₃	Н	СН
D-235	DMP	DIPP	CF ₃	Н	СН
D-236	DMP	DIPP	F	Н	СН
D-237	DMP	DIPP	Н	tBu	СН
D-238	DMP	DIPP	Н	SiMe ₃	СН
D-239	DMP	DIPP	Н	CF ₃	СН
D-240	DMP	DIPP	Н	F	СН
D-241	DMP	DIPP	Н	CN	CH
D-242	DMP	TMP	Н	Н	СН
D-243	DMP	TMP	tBu	Н	СН
D-244	DMP	TMP	SiMe ₃	Н	СН
D-245	DMP	TMP	CF ₃	Н	СН

D 040	DMD	TNAD	_		011
D-246	DMP	TMP	F	Н	СН
D-247	DMP	TMP	Н	tBu	СН
D-248	DMP	TMP	Н	SiMe ₃	СН
D-249	DMP	TMP	Н	CF ₃	СН
D-250	DMP	TMP	Н	F	СН
D-251	DMP	TMP	Н	CN	СН
D-252	DIPP	Me	Н	Н	СН
D-253	DIPP	Me	tBu	Н	СН
D-254	DIPP	Me	SiMe₃	Н	СН
D-255	DIPP	Me	CF ₃	Н	СН
D-256	DIPP	Me	F	Н	СН
D-257	DIPP	Me	Н	tBu	СН
D-258	DIPP	Me	Н	SiMe ₃	СН
D-259	DIPP	Me	Н	CF ₃	СН
D-260	DIPP	Me	Н	F	СН
D-261	DIPP	Me	Н	CN	CH
D-262	DIPP	tBu	Н	Н	СН
D-263	DIPP	tBu	tBu	Н	СН
D-264	DIPP	tBu	SiMe₃	Н	СН
D-265	DIPP	tBu	CF ₃	Н	СН
D-266	DIPP	tBu	F	Н	СН
D-267	DIPP	tBu	Н	tBu	СН
D-268	DIPP	tBu	Н	SiMe ₃	СН
D-269	DIPP	tBu	Н	CF ₃	СН
D-270	DIPP	tBu	Н	F	СН
D-271	DIPP	tBu	Н	CN	СН
D-272	DIPP	Ph	Н	Н	СН
D-273	DIPP	Ph	tBu	Н	СН
D-274	DIPP	Ph	SiMe ₃	Н	СН
D-275	DIPP	Ph	CF ₃	Н	СН
D-276	DIPP	Ph	F	Н	СН
D-277	DIPP	Ph	Н	tBu	СН
D-278	DIPP	Ph	Н	SiMe ₃	СН
D-279	DIPP	Ph	Н	CF ₃	СН
D-280	DIPP	Ph	Н	F	СН
D-281	DIPP	Ph	Н	CN	СН
D-282	DIPP	DIPP	Н	Н	СН
D-283	DIPP	DIPP	tBu	Н	СН
D-284	DIPP	DIPP	SiMe ₃	Н	СН
D-285	DIPP	DIPP	CF ₃	Н	СН
D-286	DIPP	DIPP	F	Н	СН
D-287	DIPP	DIPP	Н	tBu	СН
D-288	DIPP	DIPP	Н	SiMe ₃	СН

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D-289	DIPP	DIPP	Н	CF ₃	СН
D-290	DIPP	DIPP	Н	F	СН
D-291	DIPP	DIPP	Н	CN	СН
D-292	DIPP	TMP	Н	Н	СН
D-293	DIPP	TMP	tBu	Н	СН
D-294	DIPP	TMP	SiMe ₃	Н	СН
D-295	DIPP	TMP	CF ₃	Н	СН
D-296	DIPP	TMP	F	Н	СН
D-297	DIPP	TMP	Н	tBu	СН
D-298	DIPP	TMP	Н	SiMe ₃	СН
D-299	DIPP	TMP	Н	CF ₃	СН
D-300	DIPP	TMP	Н	F	СН
D-301	DIPP	TMP	Н	CN	СН
E-1	Me	Me	Н	Н	N
E-2	Me	Me	tBu	Н	N
E-3	Me	Me	SiMe ₃	Н	N
E-4	Me	Me	CF ₃	Н	N
E-5	Me	Me	F	Н	N
E-6	Me	Me	Н	tBu	N
E-7	Me	Me	Н	SiMe ₃	N
E-8	Me	Me	Н	CF ₃	N
E-9	Me	Me	Н	F	N
E-10	Me	Me	Н	CN	N
E-11	Me	tBu	Н	Н	N
E-12	Me	tBu	tBu	Н	N
E-13	Me	tBu	SiMe₃	Н	N
E-14	Me	tBu	CF ₃	Н	N
E-15	Me	tBu	F	Н	N
E-16	Me	tBu	Н	tBu	N
E-17	Me	tBu	Н	SiMe ₃	N
E-18	Me	tBu	Н	CF ₃	N
E-19	Me	tBu	Н	F	N
E-20	Me	tBu	Н	CN	N
E-21	Me	Ph	Н	Н	N
E-22	Me	Ph	tBu	Н	N
E-23	Me	Ph	SiMe ₃	Н	N
E-24	Me	Ph	CF ₃	Н	N
E-25	Me	Ph	F	Н	N
E-26	Me	Ph	Н	tBu	N
E-27	Me	Ph	Н	SiMe ₃	N
E-28	Me	Ph	Н	CF ₃	N
E-29	Me	Ph	Н	F	N
E-30	Me	Ph	Н	CN	N

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E-31	Me	DIPP	Н	Н	N
E-32	Me	DIPP	tBu	Н	N
E-33	Me	DIPP	SiMe ₃	Н	N
E-34	Me	DIPP	CF ₃	Н	N
E-35	Me	DIPP	F	Н	N
E-36	Me	DIPP	Н	tBu	N
E-37	Me	DIPP	Н	SiMe ₃	N
E-38	Me	DIPP	Н	CF ₃	N
E-39	Me	DIPP	Н	F	N
E-40	Me	DIPP	Н	CN	N
E-41	Me	TMP	Н	Н	N
E-42	Me	TMP	tBu	Н	N
E-43	Me	TMP	SiMe ₃	Н	N
E-44	Me	TMP	CF ₃	Н	N
E-45	Me	TMP	F	Н	N
E-46	Me	TMP	Н	tBu	N
E-47	Me	TMP	Н	SiMe ₃	N
E-48	Me	TMP	Н	CF ₃	N
E-49	Me	TMP	Н	F	N
E-50	Me	TMP	Н	CN	N
E-51	iPr	Me	Н	Н	N
E-52	iPr	Me	tBu	Н	N
E-53	iPr	Me	SiMe₃	Н	N
E-55	iPr	Me	CF ₃	Н	N
E-56	iPr	Me	F	Н	N
E-57	iPr	Me	Н	tBu	N
E-58	iPr	Me	Н	SiMe ₃	N
E-59	iPr	Me	Н	CF ₃	N
E-60	iPr	Me	Н	F	N
E-61	iPr	Me	Н	CN	N
E-62	iPr	tBu	Н	Н	N
E-63	iPr	tBu	tBu	Н	N
E-64	iPr	tBu	SiMe ₃	Н	N
E-65	iPr	tBu	CF ₃	Н	N
E-66	iPr	tBu	F	Н	N
E-67	iPr	tBu	Н	tBu	N
E-68	iPr	tBu	Н	SiMe ₃	N
E-69	iPr	tBu	Н	CF ₃	N
E-70	iPr	tBu	Н	F	N
E-71	iPr	tBu	Н	CN	N
E-72	iPr	Ph	Н	Н	N
E-73	iPr	Ph	tBu	Н	N
E-74	iPr	Ph	SiMe ₃	Н	N

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E-75	iPr	Ph	CF ₃	Н	N
E-76	iPr	Ph	F	Н	N
E-77	iPr	Ph	Н	tBu	N
E-78	iPr	Ph	Н	SiMe ₃	N
E-79	iPr	Ph	Н	CF ₃	N
E-80	iPr	Ph	Н	F	N
E-81	iPr	Ph	Н	CN	N
E-82	iPr	DIPP	Н	Н	N
E-83	iPr	DIPP	tBu	Н	N
E-84	iPr	DIPP	SiMe₃	Н	N
E-85	iPr	DIPP	CF ₃	Н	N
E-86	iPr	DIPP	F	Н	N
E-87	iPr	DIPP	Н	tBu	N
E-88	iPr	DIPP	Н	SiMe ₃	N
E-89	iPr	DIPP	Н	CF ₃	N
E-90	iPr	DIPP	Н	F	N
E-91	iPr	DIPP	Н	CN	N
E-92	iPr	TMP	Н	Н	N
E-93	iPr	TMP	tBu	Н	N
E-94	iPr	TMP	SiMe ₃	Н	N
E-95	iPr	TMP	CF ₃	Н	N
E-96	iPr	TMP	F	Н	N
E-97	iPr	TMP	Н	tBu	N
E-98	iPr	TMP	Н	SiMe ₃	N
E-99	iPr	TMP	Н	CF ₃	N
E-100	iPr	TMP	Н	F	N
E-101	iPr	TMP	Н	CN	N
E-102	Ph	Me	Н	Н	N
E-103	3-tBu-Ph	Me	tBu	Н	N
E-104	3-(Me₃Si)Ph	Me	SiMe ₃	Н	N
E-105	3-(F ₃ C)Ph	Me	CF ₃	Н	N
E-106	3-F-Ph	Me	F	Н	N
E-107	4-tBu-Ph	Me	Н	tBu	N
E-108	4-(Me₃Si)Ph	Me	Н	SiMe ₃	N
E-109	4-(F ₃ C)Ph	Me	Н	CF ₃	N
E-110	4-F-Ph	Me	Н	F	N
E-111	4-NC-Ph	Me	Н	CN	N
E-112	Ph	tBu	Н	Н	N
E-113	3-tBu-Ph	tBu	tBu	Н	N
E-114	3-(Me₃Si)Ph	tBu	SiMe ₃	Н	N
E-115	3-(F ₃ C)Ph	tBu	CF ₃	Н	N
E-116	3-F-Ph	tBu	F	Н	N
E-117	4-tBu-Ph	tBu	Н	tBu	N

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E-118	4-(Me₃Si)Ph	tBu	Н	SiMe₃	N
E-119	4-(F ₃ C)Ph	tBu	Н	CF ₃	N
E-120	4-F-Ph	tBu	Н	F	N
E-121	4-NC-Ph	tBu	Н	CN	N
E-122	Ph	Ph	Н	Н	N
E-123	3-tBu-Ph	Ph	tBu	Н	N
E-124	3-(Me ₃ Si)Ph	Ph	SiMe ₃	Н	N
E-125	3-(F ₃ C)Ph	Ph	CF ₃	Н	N
E-126	3-F-Ph	Ph	F	Н	N
E-127	4-tBu-Ph	Ph	Н	tBu	N
E-128	4-(Me₃Si)Ph	Ph	Н	SiMe ₃	N
E-129	4-(F ₃ C)Ph	Ph	Н	CF ₃	N
E-130	4-F-Ph	Ph	Н	F	N
E-131	4-NC-Ph	Ph	Н	CN	N
E-132	Ph	DIPP	Н	Н	N
E-133	3-tBu-Ph	DIPP	tBu	Н	N
E-134	3-(Me₃Si)Ph	DIPP	SiMe ₃	Н	N
E-135	3-(F ₃ C)Ph	DIPP	CF ₃	Н	N
E-136	3-F-Ph	DIPP	F	Н	N
E-137	4-tBu-Ph	DIPP	Н	tBu	N
E-138	4-(Me ₃ Si)Ph	DIPP	Н	SiMe ₃	N
E-139	4-(F ₃ C)Ph	DIPP	Н	CF ₃	N
E-140	4-F-Ph	DIPP	Н	F	N
E-141	4-NC-Ph	DIPP	Н	CN	N
E-142	Ph	TMP	Н	Н	N
E-143	3-tBu-Ph	TMP	tBu	Н	N
E-144	3-(Me₃Si)Ph	TMP	SiMe ₃	Н	N
E-145	3-(F₃C)Ph	TMP	CF ₃	Н	N
E-146	3-F-Ph	TMP	F	Н	N
E-147	4-tBu-Ph	TMP	Н	tBu	N
E-148	4-(Me ₃ Si)Ph	TMP	Н	SiMe ₃	N
E-149	4-(F ₃ C)Ph	TMP	Н	CF ₃	N
E-150	4-F-Ph	TMP	Н	F	N
E-151	4-NC-Ph	TMP	Н	CN	N
E-152	TMP	Me	Н	Н	N
E-153	TMP	Me	tBu	Н	N
E-154	TMP	Me	SiMe ₃	Н	N
E-155	TMP	Me	CF ₃	Н	N
E-156	TMP	Me	F	Н	N
E-157	TMP	Me	Н	tBu	N
E-158	TMP	Me	Н	SiMe ₃	N
E-159	TMP	Me	Н	CF ₃	N
E-160	TMP	Me	Н	F	N

E-161	TMP	Me	Н	CN	N
E-162	TMP	tBu	Н	Н	N
E-163	TMP	tBu	tBu	Н	N
E-164	TMP	tBu	SiMe ₃	Н	N
E-165	TMP	tBu	CF ₃	Н	N
E-166	TMP	tBu	F	Н	N
E-167	TMP	tBu	Н	tBu	N
E-168	TMP	tBu	Н	SiMe ₃	N
E-169	TMP	tBu	Н	CF ₃	N
E-170	TMP	tBu	Н	F	N
E-171	TMP	tBu	Н	CN	N
E-172	TMP	Ph	Н	Н	N
E-173	TMP	Ph	tBu	Н	N
E-174	TMP	Ph	SiMe ₃	Н	N
E-175	TMP	Ph	CF ₃	Н	N
E-176	TMP	Ph	F	Н	N
E-177	TMP	Ph	Н	tBu	N
E-178	TMP	Ph	Н	SiMe ₃	N
E-179	TMP	Ph	Н	CF ₃	N
E-180	TMP	Ph	Н	F	N
E-181	TMP	Ph	Н	CN	N
E-182	TMP	DIPP	Н	Н	N
E-183	TMP	DIPP	tBu	Н	N
E-184	TMP	DIPP	SiMe ₃	Н	N
E-185	TMP	DIPP	CF ₃	Н	N
E-186	TMP	DIPP	F	Н	N
E-187	TMP	DIPP	Н	tBu	N
E-188	TMP	DIPP	Н	SiMe ₃	N
E-189	TMP	DIPP	Н	CF ₃	N
E-190	TMP	DIPP	Н	F	N
E-191	TMP	DIPP	Н	CN	N
E-192	TMP	TMP	Н	Н	N
E-193	TMP	TMP	tBu	Н	N
E-194	TMP	TMP	SiMe ₃	Н	N
E-195	TMP	TMP	CF ₃	Н	N
E-196	TMP	TMP	F	Н	N
E-197	TMP	TMP	Н	tBu	N
E-198	TMP	TMP	Н	SiMe ₃	N
E-199	TMP	TMP	Н	CF ₃	N
E-200	TMP	TMP	Н	F	N
E-201	TMP	TMP	Н	CN	N
E-202	DMP	Me	Н	Н	N
E-203	DMP	Me	tBu	H	N

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E-204	DMP	Me	SiMe ₃	Н	N
E-205	DMP	Me	CF ₃	Н	N
E-206	DMP	Me	F	Н	N
E-207	DMP	Me	Н	tBu	N
E-208	DMP	Me	Н	SiMe₃	N
E-209	DMP	Me	Н	CF ₃	N
E-210	DMP	Me	Н	F	N
E-211	DMP	Me	Н	CN	N
E-212	DMP	tBu	Н	Н	N
E-213	DMP	tBu	tBu	Н	N
E-214	DMP	tBu	SiMe ₃	Н	N
E-215	DMP	tBu	CF ₃	Н	N
E-216	DMP	tBu	F	Н	N
E-217	DMP	tBu	Н	tBu	N
E-218	DMP	tBu	Н	SiMe ₃	N
E-219	DMP	tBu	Н	CF ₃	N
E-220	DMP	tBu	Н	F	N
E-221	DMP	tBu	Н	CN	N
E-222	DMP	Ph	Н	Н	N
E-223	DMP	Ph	tBu	Н	N
E-224	DMP	Ph	SiMe ₃	Н	N
E-225	DMP	Ph	CF ₃	Н	N
E-226	DMP	Ph	F	Н	N
E-227	DMP	Ph	Н	tBu	N
E-228	DMP	Ph	Н	SiMe ₃	N
E-229	DMP	Ph	Н	CF ₃	N
E-230	DMP	Ph	Н	F	N
E-231	DMP	Ph	Н	CN	N
E-232	DMP	DIPP	Н	Н	N
E-233	DMP	DIPP	tBu	Н	N
E-234	DMP	DIPP	SiMe ₃	Н	N
E-235	DMP	DIPP	CF ₃	Н	N
E-236	DMP	DIPP	F	Н	N
E-237	DMP	DIPP	Н	tBu	N
E-238	DMP	DIPP	Н	SiMe ₃	N
E-239	DMP	DIPP	Н	CF ₃	N
E-240	DMP	DIPP	Н	F	N
E-241	DMP	DIPP	Н	CN	N
E-242	DMP	TMP	Н	Н	N
E-243	DMP	TMP	tBu	Н	N
E-244	DMP	TMP	SiMe ₃	Н	N
E-245	DMP	TMP	CF ₃	Н	N
E-246	DMP	TMP	F	Н	N

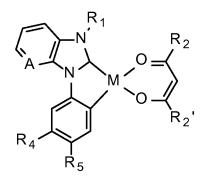
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	T	1	1	1	I
E-247	DMP	TMP	Н	tBu	N
E-248	DMP	TMP	Н	SiMe ₃	N
E-249	DMP	TMP	Н	CF ₃	N
E-250	DMP	TMP	Н	F	N
E-251	DMP	TMP	Н	CN	N
E-252	DIPP	Me	Н	Н	N
E-253	DIPP	Me	tBu	Н	N
E-254	DIPP	Me	SiMe ₃	Н	N
E-255	DIPP	Me	CF ₃	Н	N
E-256	DIPP	Me	F	Н	N
E-257	DIPP	Me	Н	tBu	N
E-258	DIPP	Me	Н	SiMe ₃	N
E-259	DIPP	Me	Н	CF ₃	N
E-260	DIPP	Me	Н	F	N
E-261	DIPP	Me	Н	CN	N
E-262	DIPP	tBu	Н	Н	N
E-263	DIPP	tBu	tBu	Н	N
E-264	DIPP	tBu	SiMe ₃	Н	N
E-265	DIPP	tBu	CF ₃	Н	N
E-266	DIPP	tBu	F	Н	N
E-267	DIPP	tBu	Н	tBu	N
E-268	DIPP	tBu	Н	SiMe ₃	N
E-269	DIPP	tBu	Н	CF ₃	N
E-270	DIPP	tBu	Н	F	N
E-271	DIPP	tBu	Н	CN	N
E-272	DIPP	Ph	Н	Н	N
E-273	DIPP	Ph	tBu	Н	N
E-274	DIPP	Ph	SiMe₃	Н	N
E-275	DIPP	Ph	CF ₃	Н	N
E-276	DIPP	Ph	F	Н	N
E-277	DIPP	Ph	Н	tBu	N
E-278	DIPP	Ph	Н	SiMe ₃	N
E-279	DIPP	Ph	Н	CF ₃	N
E-280	DIPP	Ph	Н	F	N
E-281	DIPP	Ph	Н	CN	N
E-282	DIPP	DIPP	Н	Н	N
E-283	DIPP	DIPP	tBu	Н	N
E-284	DIPP	DIPP	SiMe ₃	Н	N
E-285	DIPP	DIPP	CF ₃	Н	N
E-286	DIPP	DIPP	F	Н	N
E-287	DIPP	DIPP	Н	tBu	N
E-288	DIPP	DIPP	Н	SiMe ₃	N
E-289	DIPP	DIPP	Н	CF ₃	N
L	I	I	I	I	l

DIPP	DIPP	Н	F	N
DIPP	DIPP	Н	CN	N
DIPP	TMP	Н	Н	N
DIPP	TMP	tBu	Н	N
DIPP	TMP	SiMe₃	Н	N
DIPP	TMP	CF ₃	Н	N
DIPP	TMP	F	Н	N
DIPP	TMP	Н	tBu	N
DIPP	TMP	Н	SiMe ₃	N
DIPP	TMP	Н	CF ₃	N
DIPP	TMP	Н	F	N
DIPP	TMP	Н	CN	N
	DIPP DIPP DIPP DIPP DIPP DIPP DIPP DIPP	DIPP DIPP DIPP TMP	DIPP DIPP H DIPP TMP H DIPP TMP tBu DIPP TMP SiMe3 DIPP TMP CF3 DIPP TMP F DIPP TMP H DIPP TMP H DIPP TMP H	DIPP DIPP H CN DIPP TMP H H DIPP TMP tBu H DIPP TMP SiMe3 H DIPP TMP CF3 H DIPP TMP F H DIPP TMP H tBu DIPP TMP H CF3 DIPP TMP H CF3 DIPP TMP H SiMe3

DIPP = 2,6-Diisopropylphenyl, TIPP = 2,4,6-Triisopropylphenyl, TMP = 2,4,6-Trimethylphenyl, DMP = 3,5-Dimethylphenyl.

In a particularly preferred embodiment the present invention is directed to compounds of formula



, wherein

A is CH, or N; preferably CH;

$$R_8$$
 R_8 R_8

 R_1 is phenyl,

, wherein R_8 is C_1 - C_4 alkyl and $R_{8^{\prime}}$ is

$$R_9$$
 , or

H, or C₁-C₄alkyl;

, wherein R_9 is CF_3 , $C_1\text{-}C_4$ alkyl, F, or

10 Si(CH₃)₃;

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R₂ and R₂ are C₁-C₆alkyl, especially methyl, or tert-butyl; phenyl, or a group of formula

$$R_7$$
 R_7

, wherein R_7 is C_1 - C_4 alkyl and $R_{7'}$ is H, or C_1 - C_4 alkyl;

R₄ is H, CF₃, or C₁-C₄alkyl, especially tert-butyl; and

R₅ is H, CF₃, or C₁-C₄alkyl, especially tert-butyl.

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A process for preparing the metal-carbene complexes according to the present invention comprises by contacting suitable compounds comprising M with compounds of the general

$$A = A \qquad R_1$$

$$A \cdot A \qquad N^+ \qquad X^-$$

$$R_4 \qquad R_5$$

formula

(IV), wherein

R₁, R₄, R₅ and A are each as defined above and

10 X is F, Cl, Br, I, PF₆, or BF₄.

Customary processes involve, for example, the deprotonation of the imidazole ligand precursors of formula (IV) and subsequent reaction, generally in situ, with suitable Pt/Pd-comprising metal compounds and optionally precursors of ligand L.

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The process for preparing the inventive metal-carbene complexes is illustrated below in more detail on basis of inventive platinum-carbene complexes of formula I, wherein L is a

$$R_2$$
 R_2

ligand of formula

, but is not limited thereto.

20 The process comprises the following steps:

- (i) the deprotonation of the imidazole ligand precursors of formula (IV);
- (ii) subsequent reaction with suitable Pt-comprising metal compounds; and

(iii) reaction of the intermediate obtained in step ii) with HL in the presence of a base.

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Deprotonation in step i) can be accomplished by basic compounds known to those skilled in the art, for example basic metallates, basic metal acetates, acetylacetonates or alkoxylates, or bases such as KOtBu, NaOtBu, LiOtBu, NaH, silylamides and phosphazene bases. Preference is given to deprotonating with Ag₂O.

The deprotonation is preferably effected in a solvent. Suitable solvents are known per se to those skilled in the art and are preferably selected from the group consisting of aromatic and aliphatic solvents, ethers, alcohols, esters, amides, ketones, nitriles, halogenated compounds and mixtures thereof. A particularly preferred solvent is dioxane.

The reaction is effected generally at a temperature of 0 to 50°C. The reaction time depends on the desired Pt-carbene complex and is generally 1 to 80 hours, preferably 2 to 70 hours, more preferably 10 to 60 hours.

Then the deprotonated imidazole ligand precursors of formula (IV) are reacted with suitable Pt-comprising metal compounds.

In general, suitable Pt salts are all of those which are known to those skilled in the art and exhibit a sufficiently high reactivity under the inventive reaction conditions. Preference is given to corresponding Pt salts or complexes selected from the group consisting of Pt(COD)Cl₂ (COD = cyclooctadiene), Pt(PPh₃)₂Cl₂, Pt(pyridine)₂Cl₂, [PtMe₂(SMe₂)]₂, Pt(SMe₂)₂Cl₂, Pt(SEt₂)₂Cl₂, Pt(phenanthroline)Cl₂, Pt(NH₃)₂Cl₂, PtCl₂, K₂PtCl₄ and mixtures thereof, particular preference being given to using Pt(COD)Cl₂.

The reaction is preferably effected in a solvent. Suitable solvents are known per se to those skilled in the art and are preferably selected from the group consisting of aromatic and aliphatic solvents, ethers, alcohols, esters, amides, ketones, nitriles, halogenated compounds and mixtures thereof. A particularly preferred solvent is a mixture of dioxane and 2-butanone.

The reaction is effected generally at a temperature of 0 to 150°C. The reaction time depends on the desired Pt-carbene complex and is generally 1 to 80 hours, preferably 2 to 70 hours, more preferably 10 to 60 hours.

Afterwards all volatiles are removed and the intermediate obtained in step ii) is reacted with HL in the presence of a base, such as, for example, potassium tert-butanolate. The reaction is preferably effected in a solvent, such as, for example, dimethyl formamide.

The reaction is effected generally at a temperature of 0 to 150°C. The reaction time depends on the desired Pt-carbene complex and is generally 1 to 80 hours.

The resulting inventive metal-carbene complex is worked up by methods known to those skilled in the art. For example, the product which precipitates out during the reaction is filtered, washed and then dried. Flash chromatography and/or recrystallization affords high-purity inventive metal-carbene complexes.

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In the context of the present invention, the terms aryl radical, unit or group, heteroaryl radical, unit or group, alkyl radical, unit or group, cycloalkyl radical, unit or group, and groups with donor or acceptor action are each defined as follows – unless stated otherwise:

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Aryl radicals or substituted or unsubstituted aryl radicals having 6 to 30 carbon atoms (C_6 - C_{30} -aryl radicals) refer in the present invention to radicals which are derived from monocyclic, bicyclic or tricyclic aromatics which do not comprise any ring heteroatoms. When the systems are not monocyclic systems, the term " aryl" for the second ring also includes the saturated form (perhydro form) or the partly unsaturated form (for example the dihydro form or tetrahydro form), provided that the particular forms are known and stable. This means that the term " aryl" in the present invention encompasses, for example, also bicyclic or tricyclic radicals in which either both or all three radicals are aromatic, and bicyclic or tricyclic radicals in which only one ring is aromatic, and also tricyclic radicals in which two rings are aromatic. Examples of aryl are: phenyl, naphthyl, indanyl, 1,2-dihydronaphthenyl, 1,4-dihydronaphthenyl, indenyl, anthracenyl, phenanthrenyl or 1,2,3,4-tetrahydronaphthyl. Particular preference is given to C_6 -aryl radicals, for example phenyl or naphthyl, very particular preference to C_6 -aryl radicals, for example phenyl.

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The aryl radicals or C_6 - C_{30} -aryl radicals may be unsubstituted or substituted by one or more further radicals. Suitable further radicals are selected from the group consisting of C_1 - C_{20} -alkyl, C_6 - C_{30} -aryl and substituents with donor or acceptor action, suitable substituents with donor or acceptor action are specified below. The C_6 - C_{30} -aryl radicals are preferably unsubstituted or substituted by one or more C_1 - C_{20} -alkyl groups, C_1 - C_{20} -alkoxy groups, C_1 , C_{30} -aryl radicals are specified below).

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Heteroaryl radicals or substituted or unsubstituted heteroaryl radicals having a total of 5 to 18 carbon atoms and/or heteroatoms are understood to mean monocyclic, bicyclic or tricyclic heteroaromatics, some of which can be derived from the aforementioned aryl, in which at least one carbon atom in the aryl base structure has been replaced by a heteroatom. Preferred heteroatoms are N, O and S. The heteroaryl radicals more preferably have 5 to 13 ring atoms. The base structure of the heteroaryl radicals is especially preferably selected from systems such as pyridine and five-membered heteroaromatics such as thiophene, pyrrole, imidazole, thiazole, oxazole or furan. These base structures may optionally be fused to one or two six-membered aromatic radicals. Suitable fused heteroaromatics are carbazolyl, benzimidazolyl, benzofuryl, benzothiazolyl, benzoxazolyl, dibenzofuryl or dibenzothiophenyl.

The base structure may be substituted at one, more than one or all substitutable positions, suitable substituents being the same as those already specified under the definition of C_6 - C_{30} -aryl. However, the heteroaryl radicals are preferably unsubstituted. Suitable heteroaryl radicals are, for example, pyridin-2-yl, pyridin-3-yl, pyridin-4-yl, thiophen-2-yl, thiophen-3-yl, pyrrol-2-yl, pyrrol-3-yl, furan-2-yl, furan-3-yl, thiazol-2-yl, oxazol-2-yl and imidazol-2-yl, and the corresponding benzofused radicals, especially carbazolyl, benzimidazolyl, benzofuryl, benzothiazolyl, benzoxazolyl, dibenzofuryl or dibenzothiophenyl.

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An alkyl radical in the context of the present application is a linear or branched alkyl radical optionally bearing at least one functional group, optionally interrupted by at least one heteroatom and having 1 to 20 carbon atoms. Preference is given to C_1 - to C_1 -alkyl radicals, particular preference to C_1 - to C_6 -alkyl radicals. In addition, the alkyl radicals may be substituted by one or more functional groups, preferably selected from the group consisting of C_1 - C_2 0-alkyl, C_1 - C_2 0-alkoxy, halogen, preferably F, C_1 - C_2 0-haloalkyl, e.g. C_3 , and C_6 - C_3 0-aryl which may in turn be substituted or unsubstituted. Suitable aryl substituents and suitable alkoxy and halogen substituents are specified below. Examples of suitable alkyl groups are methyl, ethyl, propyl, butyl, pentyl, hexyl, heptyl and octyl, and also C_1 - C_2 0-alkyl-, C_1 - C_2 0-haloalkyl-, C_6 - C_3 0-aryl-, C_1 - C_2 0-alkoxy- and/or halogen-substituted, especially F-substituted, derivatives of the alkyl groups mentioned, for example C_3 . This comprises both the n-isomers of the radicals mentioned and branched isomers such as isopropyl, isobutyl, isopentyl, sec-butyl, tert-butyl, neopentyl, 3,3-dimethylbutyl, 3-ethylhexyl, etc. Preferred alkyl groups are methyl, ethyl, isopropyl, tert-butyl and C_3 .

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A cycloalkyl radical or a substituted or unsubstituted cycloalkyl radical having 3 to 20 carbon atoms is understood in the context of the present application to mean a substituted or unsubstituted C₃-C₂₀-cycloalkyl radical. Preferred are cycloalkyl radicals having 5 to 20, more preferably 5 to 10 and most preferably 5 to 8 carbon atoms in the base structure (ring) to understand. Suitable substituents are the substituents mentioned for the alkyl groups. Examples of suitable cycloalkyl groups, which may be unsubstituted or substituted by the radicals mentioned above for the alkyl groups, are cyclopentyl, cyclohexyl, cycloheptyl, cycloactyl, cyclononyl and cyclodecyl. They may also be polycyclic ring systems such as decalinyl, norbornyl, bornanyl or adamantyl.

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Suitable alkoxy radicals derive correspondingly from the aforementioned alkyl radicals. Examples here include OCH_3 , OC_2H_5 , OC_3H_7 , OC_4H_9 and OC_8H_{17} , and also SCH_3 , SC_2H_5 , SC_3H_7 , SC_4H_9 and SC_8H_{17} . In this context, C_3H_7 , C_4H_9 and C_8H_{17} comprise both the n-isomers and branched isomers such as isopropyl, isobutyl, sec-butyl, tert-butyl and 2-ethylhexyl. Particularly preferred alkoxy or alkylthio groups are methoxy, ethoxy, n-octyloxy, 2-ethylhexyloxy and SCH_3 .

Suitable halogen radicals or halogen substituents in the context of the present application are fluorine, chlorine, bromine and iodine, preferably fluorine, chlorine and bromine, more preferably fluorine and chlorine, most preferably fluorine.

In the context of the present application, groups with donor or acceptor action are understood to mean the following groups:

C₁-C₂₀-alkoxy, C₆-C₃₀-aryloxy, C₁-C₂₀-alkylthio, C₆-C₃₀-arylthio, SiR⁶⁴R⁶⁵R⁶⁶, halogen radicals, halogenated C₁-C₂₀-alkyl radicals, carbonyl (-CO(R⁶⁴)), carbonylthio (- C = O(SR⁶⁴)), carbonyloxy (- C = O(OR⁶⁴)), oxycarbonyl (- OC = O(R⁶⁴)), thiocarbonyl (- SC = O(R⁶⁴)), amino (-NR⁶⁴R⁶⁵), OH, pseudohalogen radicals, amido (- C = O(NR⁶⁴R⁶⁵)), -NR⁶⁴C = O(R⁶⁵), phosphonate (- P(O)(OR⁶⁴)₂, phosphate (-OP(O)(OR⁶⁴)₂), phosphine (-PR⁶⁴R⁶⁵), phosphine oxide (-P(O)R⁶⁴₂), sulfate (-OS(O)₂OR⁶⁴), sulfoxide (-S(O)_ROR⁶⁴), sulfonate (-S(O)₂OR⁶⁴), sulfonyl (-S(O)₂R⁶⁴), sulfonamide (-S(O)₂NR⁶⁴R⁶⁵), NO₂, boronic esters (-OB(OR⁶⁴)₂), imino (-C = NR⁶⁴R⁶⁵)), borane radicals, stannate radicals, hydrazine radicals, oxime radicals, nitroso groups, diazo groups, vinyl groups, sulfoximines, alanes, germanes, boroxines and borazines.

Preferred substituents with donor or acceptor action are selected from the group consisting of: C_1 - to C_{20} -alkoxy, preferably C_1 - C_6 -alkoxy, more preferably ethoxy or methoxy; C_6 - C_{30} -aryloxy, preferably C_6 - C_{10} -aryloxy, more preferably phenyloxy; $SiR^{64}R^{65}R^{66}$, where R^{64} , R^{65} and R^{66} are preferably each independently substituted or unsubstituted alkyl or substituted or unsubstituted phenyl, suitable substituents having been specified above; halogen radicals, preferably F, CI, Br, more preferably F or CI, most preferably F, halogenated C_1 - C_2 0-alkyl radicals, preferably halogenated C_1 - C_6 -alkyl radicals, most preferably fluorinated C_1 - C_6 -alkyl radicals, e.g. CF_3 , CH_2F , CHF_2 or C_2F_5 ; amino, preferably dimethylamino, diethylamino or diphenylamino; OH, pseudohalogen radicals, preferably CN, SCN or OCN, more preferably CN, $-C(O)OC_1$ - C_4 -alkyl, preferably -C(O)OMe, -C(O)OM

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Very particularly preferred substituents with donor or acceptor action are selected from the group consisting of methoxy, phenyloxy, halogenated C₁-C₄-alkyl, preferably CF₃, CH₂F, CHF₂, C₂F₅, halogen, preferably F, CN, SiR⁶⁴R⁶⁵R⁶⁶, where suitable R⁶⁴, R⁶⁵ and R⁶⁶ radicals have been specified above, diphenylamino, -C(O)OC₁-C₄-alkyl, preferably – C(O)OMe, P(O)Ph₂ and SO₂Ph.

The aforementioned groups with donor or acceptor action are not intended to rule out the possibility that further radicals and groups among those specified above may also have donor or acceptor action. For example, the aforementioned heteroaryl radicals are likewise groups with donor or acceptor action, and the C₁-C₂₀-alkyl radicals are groups with donor action.

The inventive metal-carbene complexes can be used in electronic components, for example organic electronic components selected from switching elements such as organic light-emitting diodes (OLEDs), organic photovoltaic cells (OPVs), organic field-effect

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transistors (OFETs) and light-emitting electrochemical cells (LEECs), preference being given to using the metal-carbene complexes of the formula (I) in OLEDs.

In a preferred embodiment, the organic electronic component is an OLED comprising a light-emitting layer comprising at least one inventive metal-carbene complexe.

The aforementioned inventive metal-carbene complexes and mixtures thereof are outstandingly suitable as emitter molecules in organic light-emitting diodes (OLEDs). Variations in the ligands make it possible to provide corresponding complexes which exhibit electroluminescence in a wide range of the electromagnetic spectrum. The inventive metal-carbene complexes are therefore outstandingly suitable as emitter substances and it is thus possible, with the aid of the inventive complexes as emitter substances, to provide industrially usable OLEDs.

In addition, the inventive metal-carbene complexes can be used as matrix material, charge transport material, especially hole transport material, and/or charge blocker.

The inventive metal-carbene complexes are preferably used as an emitter and/or charge transport material and/or matrix material, more preferably as an emitter.

Particular properties of the inventive metal-carbene complexes are particularly good efficiencies, good CIE color loci and long lifetimes when used in OLEDs.

The present application therefore further provides an OLED comprising at least one inventive metal-carbene complex. The inventive metal-carbene complex is used in the OLED preferably as an emitter, matrix material, charge transport material, especially hole transport material, and/or charge blocker, more preferably as an emitter and/or hole transport material, most preferably as an emitter.

The present application also provides for the use of the inventive metal-carbene complexes in OLEDs, preferably as an emitter, matrix material, charge transport material, especially hole transport material, and/or charge blocker, more preferably as an emitter and/or hole transport material, most preferably as an emitter.

35 Organic light-emitting diodes are in principle formed from a plurality of layers, e.g.:

- anode (1)
- hole-transporting layer (2)
- light-emitting layer (3)
- electron-transporting layer (4)
- 40 cathode (5)

It is, however, also possible that the OLED does not have all of the layers mentioned; for example, an OLED comprising layers (1) (anode), (3) (light-emitting layer) and (5) (cathode) is likewise suitable, in which case the functions of layers (2) (hole-transporting

layer) and (4) (electron-transporting layer) are assumed by the adjoining layers. OLEDs having layers (1), (2), (3) and (5) or layers (1), (3), (4) and (5) are likewise suitable.

The inventive metal-carbene complexes are preferably used as emitter molecules and/or matrix materials in the light-emitting layer (3). The inventive metal-carbene complexes may – in addition to use as emitter molecules and/or matrix materials in the light-emitting layer (3) or instead of use in the light-emitting layer – also be used as a charge transport material in the hole-transporting layer (2) or in the electron-transporting layer (4) and/or as a charge blocker, preference being given to use as a charge transport material in the hole-transporting layer (2) (hole transport material).

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The present application therefore further provides a light-emitting layer comprising at least one of the inventive metal-carbene complexes, preferably as emitter material and/or matrix material, more preferably as emitter material. Preferred inventive metal-carbene complexes have already been specified above.

In a further embodiment, the present invention relates to a light-emitting layer consisting of at least one inventive metal-carbene complex.

The inventive metal-carbene complexes used in accordance with the invention may be present in the light-emitting layer in substance, i.e. without further additions. However, it is also possible that, in addition to the dinuclear metal-carbene complexes used in accordance with the invention, further compounds are present in the light-emitting layer. In addition, a diluent material (matrix material) may be used. This diluent material may be a polymer, for example poly(N-vinylcarbazole) or polysilane. The diluent material may, however, likewise be a small molecule, for example 4,4' -N,N' -dicarbazolebiphenyl (CDP) or tertiary aromatic amines. When a diluent material is used, the proportion of the inventive metal-carbene complexes in the light-emitting layer is generally less than 40% by weight, preferably 3 to 30% by weight. The inventive metal-carbene complexes are preferably used in a matrix. The light-emitting layer thus preferably comprises at least one inventive metal-carbene complex and at least one matrix material.

Suitable matrix materials are – in addition to the aforementioned dilution materials – in principle the materials specified hereinafter as hole and electron transport materials, and also carben complexes, for example, the inventive metal-carbene complexes, or the carbene complexes mentioned in WO 2005/019373. Particularly suitable are carbazole derivatives, for example 4,4'-bis(carbazol-9-yl)-2,2'-dimethylbiphenyl (CDBP), 4,4'-bis(carbazol-9-yl)biphenyl (CBP), 1,3-bis(N-carbazolyl)benzene (mCP), and the matrix materials specified in the following applications: WO2008/034758, WO2009/003919.

Further suitable matrix materials, which may be small molecules or (co)polymers of the small molecules mentioned, are specified in the following publications: WO2007108459 (H-1 to H-37), preferably H-20 to H-22 and H-32 to H-37, most preferably H-20, H-32, H-36, H-37, WO2008035571 A1 (Host 1 to Host 6), JP2010135467 (compounds 1 to 46)

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and Host-1 to Host-39 and Host-43), WO2009008100 compounds No.1 to No.67, preferably No.3, No.4, No.7 to No. 12, No.55, No.59, No. 63 to No.67, more preferably No. 4, No. 8 to No. 12, No. 55, No. 59, No.64, No.65, and No. 67, WO2009008099 compounds No. 1 to No. 110, WO2008140114 compounds 1-1 to 1-50, WO2008090912 compounds OC-7 to OC-36 and the polymers of Mo-42 to Mo-51, JP2008084913 H-1 to H-70, WO2007077810 compounds 1 to 44, preferably 1, 2, 4-6, 8, 19-22, 26, 28-30, 32, 36, 39-44, WO201001830 the polymers of monomers 1-1 to 1-9, preferably of 1-3, 1-7, and 1-9, WO2008029729 the (polymers of) compounds 1-1 to 1-36, WO20100443342 HS-1 to HS-101 and BH-1 to BH-17, preferably BH-1 to BH-17, JP2009182298 the (co)polymers based on the monomers 1 to 75, JP2009170764, JP2009135183 the (co)polymers based on the monomers 1-14, WO2009063757 preferably the (co)polymers based on the monomers 1-1 to 1-26, WO2008146838 the compounds a-1 to a-43 and 1-1 to 1-46, JP2008207520 the (co)polymers based on the monomers 1-1 to 1-26, JP2008066569 the (co)polymers based on the monomers 1-1 to 1-16, WO2008029652 the (co)polymers based on the monomers 1-1 to 1-52, WO2007114244 the (co)polymers based on the monomers 1-1 to 1-18, JP2010040830 the compounds HA-1 to HA-20, HB-1 to HB-16, HC-1 to HC-23 and the (co)polymers based on the monomers HD-1 to HD-12, JP2009021336, WO2010090077 the compounds 1 to 55, WO2010079678 the compounds H1 to H42, WO2010067746, WO2010044342 the compounds HS-1 to HS-101 and Poly-1 to Poly-4, JP2010114180 the compounds PH-1 to PH-36, US2009284138 the compounds 1 to 111 and H1 to H71, WO2008072596 the compounds 1 to 45, JP2010021336 the compounds H-1 to H-38, preferably H-1, WO2010004877 the compounds H-1 to H-60, JP2009267255 the compounds 1-1 to 1-105, WO2009104488 the compounds 1-1 to 1-38, WO2009086028, US2009153034, US2009134784, WO2009084413 the compounds 2-1 to 2-56, JP2009114369 the compounds 2-1 to 2-40, JP2009114370 the compounds 1 to 67, WO2009060742 the compounds 2-1 to 2-56, WO2009060757 the compounds 1-1 to 1-76, WO2009060780 the compounds 1-1 to 1-70, WO2009060779 the compounds 1-1 to 1-42, WO2008156105 the compounds 1 to 54, JP2009059767 the compounds 1 to 20, JP2008074939 the compounds 1 to 256, JP2008021687 the compounds 1 to 50, WO2007119816 the compounds 1 to 37, WO2010087222 the compounds H-1 to H-31, WO2010095564 the compounds HOST-1 to HOST-61, WO2007108362, WO2009003898, WO2010040777, WO2009003919. US2007224446, WO06128800 and PCT/EP2012/055064.

In a particularly preferred embodiment, one or more compounds of the general formula (X) specified hereinafter are used as matrix material. Preferred embodiments of the compounds of the general formula (X) are likewise specified hereinafter.

The individual layers among the aforementioned layers of the OLED may in turn be formed from two or more layers. For example, the hole-transporting layer may be formed from one layer, into which holes are injected from the electrode, and a layer which transports the holes away from the hole-injecting layer into the light-emitting layer. The electron-transporting layer may likewise consist of a plurality of layers, for example of a layer in which electrons are injected through the electrode and a layer which receives

electrons from the electron-injecting layer and transports them into the light-emitting layer. These layers mentioned are each selected according to factors such as energy level, thermal resistance and charge carrier mobility, and also energy difference of the layers mentioned with the organic layers or the metal electrodes. The person skilled in the art is capable of selecting the construction of the OLEDs such that it is matched optimally to the inventive metal-carbene complexes used as emitter substances in accordance with the invention.

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In order to obtain particularly efficient OLEDs, the HOMO (highest occupied molecular orbital) of the hole-transporting layer should be aligned to the work function of the anode, and the LUMO (lowest unoccupied molecular orbital) of the electron-transporting layer should be aligned to the work function of the cathode.

The present application further provides an OLED comprising at least one inventive light-emitting layer. The further layers in the OLED may be formed from any material which is typically used in such layers and is known to those skilled in the art.

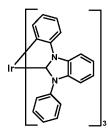
Suitable materials for the aforementioned layers (anode, cathode, hole and electron injection materials, hole and electron transport materials and hole and electron blocker materials, matrix materials, fluorescence and phosphorescence emitters) are known to those skilled in the art and are specified, for example, in H. Meng, N. Herron, *Organic Small Molecule Materials for Organic Light-Emitting Devices* in *Organic Light-Emitting Materials and Devices*, eds: Z. Li, H. Meng, Taylor & Francis, 2007, Chapter 3, pages 295 to 411.

The anode is an electrode which provides positive charge carriers. It may be composed, for example, of materials which comprise a metal, a mixture of different metals, a metal alloy, a metal oxide or a mixture of different metal oxides. Alternatively, the anode may be a conductive polymer. Suitable metals comprise the metals of groups 11, 4, 5 and 6 of the Periodic Table of the Elements, and also the transition metals of groups 8 to 10. When the anode is to be transparent, mixed metal oxides of groups 12, 13 and 14 of the Periodic Table of the Elements are generally used, for example indium tin oxide (ITO). It is likewise possible that the anode (1) comprises an organic material, for example polyaniline, as described, for example, in Nature, Vol. 357, pages 477 to 479 (June 11, 1992). At least either the anode or the cathode should be at least partly transparent in order to be able to emit the light formed.

Suitable hole transport materials for layer (2) of the inventive OLED are disclosed, for example, in Kirk-Othmer Encyclopedia of Chemical Technology, 4th Edition, Vol. 18, pages 837 to 860, 1996. Either hole-transporting molecules or polymers may be used as the hole transport material. Customarily used hole-transporting molecules are selected from the group consisting of 4,4'-bis[N-(1-naphthyl)-N-phenylamino]biphenyl (α -NPD), N,N' -diphenyl-N,N' -bis(3-methylphenyl)-[1,1' -biphenyl]-4,4' -diamine (TPD), 1,1-bis[(di-4-tolylamino)phenyl]cyclohexane (TAPC), N,N' -bis(4-methylphenyl)-N,N' -bis(4-ethylphenyl)-[1,1' -(3,3' -dimethyl)biphenyl]-4,4' -diamine (ETPD),

tetrakis(3-methylphenyl)-N,N,N',N',-2,5-phenylenediamine (PDA), α-phenyl-4-N,N-diphenylaminostyrene (TPS), p-(diethylamino)benzaldehyde diphenylhydrazone (DEH), triphenylamine (TPA), bis[4-(N,N-diethylamino)-2-methylphenyl](4-methylphenyl)methane (MPMP), 1-phenyl-3-[p-(diethylamino)styryl]-5-[p-(diethylamino)phenyl]pyrazoline (PPR or DEASP), 1,2-trans-bis(9H-carbazol-9-yl)-cyclobutane (DCZB), N,N,N', N' -tetrakis(4-methylphenyl)-(1,1' -biphenyl)-4,4' -diamine (TTB), fluorine compounds such as 2,2',7,7'-tetra(N,N-di-tolyl)amino-9,9-spirobifluorene (spiro-TTB), N,N'-bis(naphthalen-1-yl)-N,N'-bis(phenyl)-9,9-spirobifluorene (spiro-NPB) and 9,9-bis(4-(N,N-bis-biphenyl-4-yl-amino)phenyl-9Hfluorene, benzidine compounds such as N,N' -bis(naphthalen-1-yl)-N,N' -bis(phenyl)benzidine and porphyrin compounds such as copper phthalocyanines. In addition, polymeric hole-injection materials can be used such as poly(N-vinylcarbazole) (PVK), polythiophenes, polypyrrole, polyaniline, self-doping polymers, such as, for example, sulfonated poly(thiophene-3-[2](2-methoxyethoxy)ethoxy]-2,5-diyl) (Plexcore® OC Conducting Inks commercially available from Plextronics), and copolymers such as poly(3,4-ethylenedioxythiophene)/poly(4-styrenesulfonate) also called PEDOT/PSS.

In addition - in one embodiment - it is possible to use the inventive metal carbene complexes as hole conductor materials, in which case the band gap of the at least one hole conductor material is generally greater than the band gap of the emitter material used. In the context of the present application, band gap is understood to mean the triplet energy. Suitable carbene complexes are, for example, the inventive carbine complexes of the general formula (I), carbene complexes as described in WO2005/019373A2, WO2006/056418 A2, WO2005/113704, WO2007/115970, WO2007/115981 and WO2008/000727. One example of a suitable carbene complex is Ir(DPBIC)₃ with the



formula: Ir(DPBIC)₃

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The hole-transporting layer may also be electronically doped in order to improve the transport properties of the materials used, in order firstly to make the layer thicknesses more generous (avoidance of pinholes/short circuits) and in order secondly to minimize the operating voltage of the device. Electronic doping is known to those skilled in the art and is disclosed, for example, in W. Gao, A. Kahn, J. Appl. Phys., Vol. 94, No. 1, 1 July 2003 (p-doped organic layers); A. G. Werner, F. Li, K. Harada, M. Pfeiffer, T. Fritz, K. Leo, Appl. Phys. Lett., Vol. 82, No. 25, 23 June 2003 and Pfeiffer et al., Organic Electronics 2003, 4, 89 - 103 and K. Walzer, B. Maennig, M. Pfeiffer, K. Leo, Chem. Soc. Rev. 2007, 107, 1233. For example it is possible to use mixtures in the hole-transporting layer, in particular mixtures which lead to electrical p-doping of the hole-transporting layer. p-Doping is achieved by the addition of oxidizing materials. These mixtures may, for example, be the following mixtures: mixtures of the abovementioned hole transport materials with at least

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one metal oxide, for example MoO₂, MoO₃, WO_x, ReO₃ and/or V₂O₅, preferably MoO₃ and/or ReO₃, more preferably ReO₃ or mixtures comprising the aforementioned hole transport materials and one or more compounds selected from 7,7,8,8-tetracyanoquinodimethane (TCNQ), 2,3,5,6-tetrafluoro-7,7,8,8-tetracyanoquinodimethane (F₄-TCNQ), 2,5-bis(2-hydroxyethoxy)-7,7,8,8-tetracyanoquinodimethane, bis(tetra-n-butylammonium)tetracyanodiphenoquinodimethane, 2,5-dimethyl-7,7,8,8-tetracyanoquinodimethane, tetracyanoethylene, 11,11,12,12-tetracyanonaphtho-2,6-quinodimethane, 2-fluoro-7,7,8,8-tetracyanoquino-dimethane, 2,5-difluoro-7,7,8,8-

naphthalen-2-ylidene)malononitrile (F₆-TNAP), Mo(tfd)₃ (from Kahn et al., J. Am. Chem. Soc. 2009, 131 (35), 12530–12531), compounds as described in EP1988587 and in EP2180029 and guinone compounds as mentioned in EP2401254.

etracyanoguinodimethane, dicyanomethylene-1,3,4,5,7,8-hexafluoro-6H-

Suitable electron-transporting materials for layer (4) of the inventive OLEDs comprise metals chelated with oxinoid compounds, such as tris(8-hydroxyquinolato)aluminum (Alq₃), compounds based on phenanthroline such as 2,9-dimethyl-4,7-diphenyl-1,10-phenanthroline (DDPA = BCP), 4,7-diphenyl-1,10-phenanthroline (Bphen), 2,4,7,9-tetraphenyl-1,10-phenanthroline, 4,7-diphenyl-1,10-phenanthroline (DPA) or phenanthroline derivatives disclosed in EP1786050, in EP1970371, or in EP1097981, and azole compounds such as 2-(4-biphenylyl)-5-(4-t-butylphenyl)-1,3,4-oxadiazole (PBD) and 3-(4-biphenylyl)-4phenyl-5-(4-t-butylphenyl)-1,2,4-triazole (TAZ). Layer (4) may serve both to ease the electron transport and as a buffer layer or as a barrier layer in order to prevent quenching of the exciton at the interfaces of the layers of the OLED. Layer (4) preferably improves the mobility of the electrons and reduces quenching of the exciton.

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It is likewise possible to use mixtures of at least two materials in the electron-transporting layer, in which case at least one material is electron-conducting. Preferably, in such mixed electron-transporting layers, at least one phenanthroline compound is used, preferably BCP, or at least one pyridine compound according to the formula (VIII) below, preferably a compound of the formula (VIIIaa) below. More preferably, in mixed electron-transporting layers, in addition to at least one phenanthroline compound, alkaline earth metal or alkali metal hydroxyquinolate complexes, for example Liq, are used. Suitable alkaline earth metal or alkali metal hydroxyquinolate complexes are specified below (formula VII). Reference is made to WO2011/157779.

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The electron-transporting layer may also be electronically doped in order to improve the transport properties of the materials used, in order firstly to make the layer thicknesses more generous (avoidance of pinholes/short circuits) and in order secondly to minimize the operating voltage of the device. Electronic doping is known to those skilled in the art and is disclosed, for example, in W. Gao, A. Kahn, J. Appl. Phys., Vol. 94, No. 1, 1 July 2003 (p-doped organic layers); A. G. Werner, F. Li, K. Harada, M. Pfeiffer, T. Fritz, K. Leo, Appl. Phys. Lett., Vol. 82, No. 25, 23 June 2003 and Pfeiffer et al., Organic Electronics 2003, 4, 89 - 103 and K. Walzer, B. Maennig, M. Pfeiffer, K. Leo, Chem. Soc. Rev. 2007, 107, 1233. For example, it is possible to use mixtures which lead to electrical n-doping of the

electron-transporting layer. n-Doping is achieved by the addition of reducing materials. These mixtures may, for example, be mixtures of the abovementioned electron transport materials with alkali/alkaline earth metals or alkali/alkaline earth metal salts, for example Li, Cs, Ca, Sr, Cs₂CO₃, with alkali metal complexes, for example 8-hydroxyquinolatolithium (Liq), and with Y, Ce, Sm, Gd, Tb, Er, Tm, Yb, Li₃N, Rb₂CO₃, dipotassium phthalate, W(hpp)₄ from EP 1786050, or with compounds as described in EP1837926B1.

The present invention therefore also relates to an inventive OLED which comprises an electron-transporting layer comprising at least two different materials, of which at least one material is electron-conducting.

In a preferred embodiment, the electron-transporting layer comprises at least one compound of the general formula (VII)

R³² and R³³ are each independently F, C₁-C₈-alkyl, or C₆-C₁₄-aryl, which is optionally substituted by one or more C₁-C₈-alkyl groups, or

two R^{32} and/or R^{33} substituents together form a fused benzene ring which is optionally substituted by one or more C_1 - C_8 -alkyl groups;

a and b are each independently 0, or 1, 2 or 3,

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20 M¹ is an alkaline metal atom or alkaline earth metal atom,

p is 1 when M1 is an alkali metal atom, p is 2 when M1 is an earth alkali metal atom.

A very particularly preferred compound of the formula (VII) is (Liq), which may be present as a single species, or in other forms such as Li_gQ_g in which g is an integer, for example Li_6Q_6 . Q is an 8-hydroxyquinolate ligand or an 8-hydroxyquinolate derivative.

In a further preferred embodiment, the electron-transporting layer comprises at least one compound of the formula (VIII),

(VIII), in which

 R^{34} , R^{35} , R^{36} , R^{37} , $R^{34'}$, $R^{35'}$, $R^{36'}$ and $R^{37'}$ are each independently H, C_1 - C_{18} -alkyl, C_1 - C_{18} -alkyl which is substituted by E and/or interrupted by D, C_6 - C_{24} -aryl, C_6 - C_{24} -aryl which is substituted by G, C_2 - C_{20} -heteroaryl or C_2 - C_{20} -heteroaryl which is substituted by G, Q is an arylene or heteroarylene group, each of which is optionally substituted by G;

5 D is -CO-; -COO-; -S-; -SO-; -SO₂-; -O-; -NR⁴⁰-; -SiR⁴⁵R⁴⁶-; -POR⁴⁷-; -CR³⁸=CR³⁹-; or -C=C-;

E is -OR44; -SR44; -NR40R41; -COR43; -COOR42; -CONR40R41; -CN; or F;

G is E, C_1 - C_{18} -alkyl, C_1 - C_{18} -alkyl which is interrupted by D , C_1 - C_{18} -perfluoroalkyl, C_1 - C_{18} -alkoxy, or C_1 - C_{18} -alkoxy which is substituted by E and/or interrupted by D,

10 in which

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 R^{38} and R^{39} are each independently H, C_6 - C_{18} -aryl; C_6 - C_{18} -aryl which is substituted by C_1 - C_{18} -alkyl or C_1 - C_{18} -alkoxy; C_1 - C_{18} -alkyl; or C_1 - C_{18} -alkyl which is interrupted by -O-; R^{40} and R^{41} are each independently C_6 - C_{18} -aryl; C_6 - C_{18} -aryl which is substituted by C_1 - C_{18} -alkyl or C_1 - C_{18} -alkoxy; C_1 - C_{18} -alkyl; or C_1 - C_{18} -alkyl which is interrupted by -O-; or R^{40} and R^{41} together form a 6-membered ring;

 R^{42} and R^{43} are each independently C_6 - C_{18} -aryl; C_6 - C_{18} -aryl which is substituted by C_1 - C_{18} -alkyl or C_1 - C_{18} -alkoxy; C_1 - C_{18} -alkyl; or C_1 - C_{18} -alkyl which is interrupted by -O-, R^{44} is C_6 - C_{18} -aryl; C_6 - C_{18} -aryl which is substituted by C_1 - C_{18} -alkyl or C_1 - C_{18} -alkoxy; C_1 - C_1 -alkyl; or C_1 - C_1 -alkyl which is interrupted by -O-,

20 R^{45} and R^{46} are each independently C_1 - C_{18} -alkyl, C_6 - C_{18} -aryl or C_6 - C_{18} -aryl which is substituted by C_1 - C_{18} -alkyl,

 R^{47} is C_1 - C_{18} -alkyl, C_6 - C_{18} -aryl or C_6 - C_{18} -aryl which is substituted by C_1 - C_{18} -alkyl.

Preferred compounds of the formula (VIII) are compounds of the formula (VIIIa)

in which Q is:

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$$\mathbb{R}^{48}$$
, \mathbb{R}^{48} , \mathbb{R}^{48} , \mathbb{R}^{48} , \mathbb{R}^{48}

R⁴⁸ is H or C₁-C₁₈-alkyl and

$$R^{48'}$$
 is H, C₁-C₁₈-alkyl or , or .

Particular preference is given to a compound of the formula (VIIIaa)

In a further, very particularly preferred embodiment, the electron-transporting layer

VIIIaa.

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In a preferred embodiment, the electron-transporting layer comprises the compound of the formula (VII) in an amount of 99 to 1% by weight, preferably 75 to 25% by weight, more preferably about 50% by weight, where the amount of the compounds of the formulae (VII) and the amount of the compounds of the formulae (VIII) adds up to a total of 100% by weight.

The preparation of the compounds of the formula (VIII) is described in J. Kido et al., Chem. Commun. (2008) 5821–5823, J. Kido et al., Chem. Mater. 20 (2008) 5951–5953 and JP2008-127326, or the compounds can be prepared analogously to the processes disclosed in the aforementioned documents.

It is likewise possible to use mixtures of alkali metal hydroxyquinolate complexes, preferably Liq, and dibenzofuran compounds in the electron-transporting layer. Reference is made to WO2011/157790. Dibenzofuran compounds A-1 to A-36 and B-1 to B-22 described in WO2011/157790 are preferred, wherein dibenzofuran compound

(A-10) is most preferred.

In a preferred embodiment, the electron-transporting layer comprises Liq in an amount of 99 to 1% by weight, preferably 75 to 25% by weight, more preferably about 50% by weight, where the amount of Liq and the amount of the dibenzofuran compound(s), especially

, adds up to a total of 100% by weight.

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In a preferred embodiment, the invention relates to an inventive OLED wherein the electron-transporting layer comprises at least one phenanthroline derivative and/or pyridine derivative.

In a further preferred embodiment, the invention relates to an inventive OLED wherein the electron-transporting layer comprises at least one phenanthroline derivative and/or pyridine derivative and at least one alkali metal hydroxyquinolate complex.

In a further preferred embodiment, the invention relates to an inventive OLED wherein the electron-transporting layer comprises at least one phenanthroline derivative and/or pyridine derivative and 8-hydroxyquinolatolithium.

Some of the materials mentioned above as hole transport materials and electron-transporting materials can fulfill several functions. For example, some of the electron-transporting materials are simultaneously hole-blocking materials if they have a low-lying HOMO.

The cathode (5) is an electrode which serves to introduce electrons or negative charge carriers. The cathode may be any metal or nonmetal which has a lower work function than the anode. Suitable materials for the cathode are selected from the group consisting of alkali metals of group 1, for example Li, Cs, alkaline earth metals of group 2, metals of group 12 of the Periodic Table of the Elements, comprising the rare earth metals and the lanthanides and actinides. In addition, metals such as aluminum, indium, calcium, barium, samarium and magnesium, and combinations thereof, may be used. In addition, lithium-comprising organometallic compounds such as 8-hydroxyquinolatolithium (Liq), CsF, NaF, KF, Cs₂CO₃ or LiF may be applied between the organic layer and the cathode as an electron injection layer in order to reduce the operating voltage.

The OLED of the present invention may additionally comprise further layers which are known to those skilled in the art. For example, a layer which eases the transport of the positive charge and/or matches the band gaps of the layers to one another may be applied between the layer (2) and the light-emitting layer (3). Alternatively, this further layer may serve as a protective layer. In an analogous manner, additional layers may be present

between the light-emitting layer (3) and the layer (4) in order to ease the transport of the negative charge and/or to match the band gaps between the layers to one another. Alternatively, this layer may serve as a protective layer.

- In a preferred embodiment, the inventive OLED, in addition to the layers (1) to (5), comprises at least one of the further layers mentioned below:
 - a hole injection layer between the anode (1) and the hole-transporting layer (2);
 - a blocking layer for electrons between the hole-transporting layer (2) and the light-emitting layer (3);
- 10 a blocking layer for holes between the light-emitting layer (3) and the electron-transporting layer (4);

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- an electron injection layer between the electron-transporting layer (4) and the cathode (5).
- As already mentioned above, however, it is also possible that the OLED does not have all of the layers (1) to (5) mentioned; for example, an OLED comprising layers (1) (anode), (3) (light-emitting layer) and (5) (cathode) is likewise suitable, in which case the functions of layers (2) (hole-transporting layer) and (4) (electron-transporting layer) are assumed by the adjoining layers. OLEDs having layers (1), (2), (3) and (5) or layers (1), (3), (4) and (5) are likewise suitable.

Those skilled in the art know how suitable materials have to be selected (for example on the basis of electrochemical investigations). Suitable materials for the individual layers are known to those skilled in the art and disclosed, for example, in WO00/70655.

In addition, it is possible that some or all of the layers (1), (2), (3), (4) and (5) have been surface-treated in order to increase the efficiency of charge carrier transport. The selection of the materials for each of the layers mentioned is preferably determined by obtaining an OLED having a high efficiency.

The inventive OLED can be produced by methods known to those skilled in the art. In general, the OLED is produced by successive vapor deposition of the individual layers onto a suitable substrate. Suitable substrates are, for example, glass, inorganic materials such as ITO or IZO or polymer films. For the vapor deposition, customary techniques may be used, such as thermal evaporation, chemical vapor deposition (CVD), physical vapor deposition (PVD) and others.

In an alternative process, the organic layers may be coated from solutions or dispersions in suitable solvents, in which case coating techniques known to those skilled in the art are employed. Suitable coating techniques are, for example, spin-coating, the casting method, the Langmuir-Blodgett ("LB") method, the inkjet printing method, dip-coating, letterpress printing, screen printing, doctor blade printing, slit-coating, roller printing, reverse roller printing, offset lithography printing, flexographic printing, web printing, spray coating, coating by a brush or pad printing, and the like. Among the processes mentioned, in

addition to the aforementioned vapor deposition, preference is given to spin-coating, the inkjet printing method and the casting method since they are particularly simple and inexpensive to perform. In the case that layers of the OLED are obtained by the spin-coating method, the casting method or the inkjet printing method, the coating can be obtained using a solution prepared by dissolving the composition in a concentration of 0.0001 to 90% by weight in a suitable organic solvent such as benzene, toluene, xylene, tetrahydrofuran, methyltetrahydrofuran, N,N-dimethylformamide, acetone, acetonitrile, anisole, dichloromethane, dimethyl sulfoxide, water and mixtures thereof.

10 It is possible that the layers of the OLED are all produced by the same coating method. Furthermore, it is likewise possible to conduct two or more different coating methods to produce the layers of the OLED.

In general, the different layers have the following thicknesses: anode (2) 500 to 5000 Å, preferably 1000 to 2000 Å (ångström); hole-transporting layer (3) 50 to 1000 Å, preferably 200 to 800 Å; light-emitting layer (4) 10 to 1000 Å, preferably 100 to 800 Å; electron-transporting layer (5) 50 to 1000 Å, preferably 200 to 800 Å; cathode (6) 200 to 10 000 Å, preferably 300 to 5000 Å. In addition, it is likewise possible to combine several layers by mixing. For example, the hole-transporting material can be mixed with the materials of the light-emitting layer and then applied together. The position of the recombination zone of holes and electrons in the inventive OLED and thus the emission spectrum of the OLED may be influenced by the relative thickness and concentration ratios of each layer. This means that the thickness of the electron transport layer should preferably be selected such that the electron/hole recombination zone is within the light-emitting layer. The ratio of the layer thicknesses of the individual layers in the OLED is dependent upon the materials used. The layer thicknesses of any additional layers used are known to those skilled in the art.

In a preferred embodiment, the present invention relates to an OLED comprising at least one inventive metal-carbene complex, and at least one compound of the general formula

$$(R^{24'})_{m1}$$
 $(R^{25'})_{n2}$ $(R^{22'})_{n2}$ (X) (X)

(X), wherein

X' is NR, S, O or $PR^{26'}$;

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R²⁶ is aryl, heteroaryl, alkyl, cycloalkyl, or heterocycloalkyl;

A¹' is -NR6' R³', -P(O)R8' R9', -PR¹0' R¹¹¹', -S(O) $_2$ R¹²', -S(O)R¹³', -SR¹⁴', or – OR¹⁵'; R²¹', R²²' and R²³' are independently of each other aryl, heteroaryl, alkyl, cycloalkyl, or heterocycloalkyl, wherein at least on of the groups R²¹', R²²', or R²³' is aryl, or heteroaryl; R²⁴' and R²⁵' are independently of each other alkyl, cycloalkyl, heterocycloalkyl, aryl, heteroaryl, a group A¹', or a group having donor, or acceptor characteristics; n² and m¹ are independently of each other 0, 1, 2, or 3;

R6' and R7' form together with the nitrogen atom a cyclic residue having 3 to 10 ring atoms, which can be unsubstituted, or which can be substituted with one, or more substituents selected from alkyl, cycloalkyl, heterocycloalkyl, aryl, heteroaryl and a group having donor, or acceptor characteristics; and/or which can be annulated with one, or more further cyclic residues having 3 to 10 ring atoms, wherein the annulated residues can be unsubstituted, or can be substituted with one, or more substituents selected from alkyl, cycloalkyl, heterocycloalkyl, aryl, heteroaryl and a group having donor, or acceptor characteristics; and

R8', R9', R10', R11', R12', R13', R14' und R15' are independently of each other aryl, heteroaryl, alkyl, cycloalkyl, or heterocycloalkyl. Compounds of formula **X**, such as, for

example, , or

, are described in WO2010079051 (in

particular pages on 19 to 26 and in tables on pages 27 to 34, pages 35 to 37 and pages 42 to 43).

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Additional matrix materials on basis of dibenzofurane are, for example, described in US2009066226, EP1885818B1, EP1970976, EP1998388 and EP2034538. Examples of particularly preferred matrix materials are shown below:

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In the above-mentioned compounds T is O, or S, preferably O. If T occurs more than one time in a molecule, all groups T have the same meaning.

In a preferred embodiment, the light-emitting layer is formed from 2 to 40% by weight, preferably 5 to 35% by weight, of at least one of the inventive metal carben complexes and 60 to 98% by weight, preferably 65 to 95% by weight, of at least one of the aforementioned matrix materials, where the sum total of the emitter material and of the matrix material adds up to 100% by weight.

In particularly preferred embodiment, the light-emitting layer comprises a matrix material,

15 such as, for example,

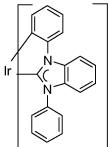
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(Ma1), and two carbene

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complexes, preferably of formula

(EM6) and



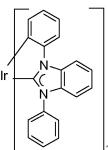
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In said embodiment, the light-emitting layer is formed from 2 to 40% by weight, preferably 5 to 35% by weight, of **EM6** and 60 to 98% by weight, preferably 65 to



95% by weight, of **Ma1** and ______, where the sum total of the carben complexes and **Ma1** adds up to 100% by weight.

Suitable metal complexes for use as matrix material and/or hole/exciton blocker material and/or electron/exciton blocker material and/or hole injection material and/or electron injection material and/or hole transport material and/or electron transport material, preferably as matrix material and/or hole/exciton blocker material, in OLEDs are thus, for example, also carbene complexes as described in WO 2005/019373 A2, WO 2006/056418 A2, WO 2005/113704, WO 2007/115970, WO 2007/115981 WO 2008/000727. Explicit reference is made here to the disclosure of the WO applications cited, and these disclosures shall be considered to be incorporated into the content of the present application.

In addition to the compounds of the formula (X), according to the present invention, it is also possible to use crosslinked or polymeric materials comprising repeat units based on the general formula (X) in crosslinked or polymerized form together with at least one inventive metal-carbene complex. Like the compounds of the general formula (X), the latter are preferably used as matrix materials.

The crosslinked or polymeric materials have outstanding solubility in organic solvents, excellent film-forming properties and relatively high glass transition temperatures. In addition, high charge carrier mobilities, high stabilities of color emission and long operating times of the corresponding components can be observed when crosslinked or polymeric materials according to the present invention are used in organic light-emitting diodes (OLEDs).

The crosslinked or polymerized materials are particularly suitable as coatings or in thin films since they are thermally and mechanically stable and relatively defect-free.

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The crosslinked or polymerized materials comprising repeating units based on the general formula (X) can be prepared by a process comprising steps (a) and (b):

- (a) preparation of a crosslinkable or polymerizable compound of the general formula
 (X) where at least one of the m1 R²⁴ radicals or at least one of the n2 R²⁵ radicals is a crosslinkable or polymerizable group attached via a spacer, and
- (b) crosslinking or polymerization of the compound of the general formula (X) obtained from step (a).

The crosslinked or polymerized materials may be homopolymers, which means that exclusively units of the general formula (X) are present in crosslinked or polymerized form. They may also be copolymers, which means that further monomers are present in addition to the units of the general formula (X), for example monomers with hole-conducting and/or electron-conducting properties, in crosslinked or polymerized form.

In a further preferred embodiment of the inventive OLED, it comprises an emission layer comprising at least one inventive metal-carbene complex, at least one matrix material of the formula (X), and optionally at least one further hole-transporting matrix material.

The inventive OLEDs can be used in all devices in which electroluminescence is useful. Suitable devices are preferably selected from stationary and mobile visual display units and illumination means. The present invention therefore also relates to a device selected from the group consisting of stationary visual display units and mobile visual display units and illumination means, comprising an inventive OLED.

Stationary visual display units are, for example, visual display units of computers, televisions, visual display units in printers, kitchen appliances and advertising panels, illuminations and information panels. Mobile visual display units are, for example, visual display units in cellphones, laptops, tablet PCs, digital cameras, mp-3 players, smartphones, vehicles, and destination displays on buses and trains.

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The inventive metal-carbene complexes can additionally be used in OLEDs with inverse structure. In these inverse OLEDs, the inventive complexes are in turn preferably used in the light-emitting layer. The structure of inverse OLEDs and the materials typically used therein are known to those skilled in the art.

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The present invention further provides a white OLED comprising at least one inventive metal-carbene complex. In a preferred embodiment, the inventive metal-carbene complexes are used as emitter material in the white OLED. Preferred embodiments of the inventive metal-carbene complexes have been specified above. In addition to the at least one inventive metal-carbene complex, the white OLED may comprise

- (i) at least one compound of the formula (X). The compound of the formula (X) is preferably used as matrix material. Preferred compounds of the formula (X) have been specified above; and/or
- 10 (ii) at least one compound of the formula (VII) and/or (IX). The compounds of the formula (VII) and/or (IX) are preferably used as electron transport material.

 Preferred compounds of the formulae (VII) and (IX) have been specified above.

In order to obtain white light, the OLED must generate light which colors the entire visible range of the spectrum. However, organic emitters normally emit only in a limited portion of the visible spectrum – i.e. are colored. White light can be generated by the combination of different emitters. Typically, red, green and blue emitters are combined. However, the prior art also discloses other methods for formation of white OLEDs, for example the triplet harvesting approach. Suitable structures for white OLEDs or methods for formation of white OLEDs are known to those skilled in the art.

In one embodiment of a white OLED, several dyes are layered one on top of another in the light-emitting layer of an OLED and hence combined (layered device). This can be achieved by mixing all dyes or by direct series connection of different-colored layers. The expression "layered OLED" and suitable embodiments are known to those skilled in the art.

In general, the different layers then have the following thicknesses: anode (2) 500 to 5000 Å (ångström), preferably 1000 to 2000 Å; hole-transporting layer (3) 50 to 1000 Å, preferably 200 to 800 Å, either a light-emitting layer comprising a mixture of different emitters (4): 10 to 1000 Å, preferably 100 to 800 Å, or several light-emitting layers in succession, each individual layer comprising a different emitter (4a, b, c, ...): each 10 to 1000 Å, preferably each 50 to 600 Å, electron-transporting layer (5) 50 to 1000 Å, preferably 200 to 800 Å, cathode (6) 200 to 10 000 Å, preferably 300 to 5000 Å.

In a further embodiment of a white OLED, several different-colored OLEDs are stacked one on top of another (stacked device). For the stacking of two OLEDs, what is called a charge generation layer (CG layer) is used. This CG layer may be formed, for example, from one electrically n-doped and one electrically p-doped transport layer. The expression "stacked OLED" and suitable embodiments are known to those skilled in the art.

In general, the different layers then have the following thicknesses: anode (2) 500 to 5000 Å (ångström), preferably 1000 to 2000 Å; first hole-transporting layer (3) 50 to 1000 Å, preferably 200 to 800 Å, first light-emitting layer (4) 10 to 1000 Å, preferably 50 to 600 Å,

first electron-transporting layer (5) 50 to 1000 Å, preferably 200 to 800 Å, electrically n-doped layer 50 to 1000 Å, preferably 100 to 800 Å, second hole-transporting layer (3) to 50 to 1000 Å, preferably 200 to 800 Å, second light-emiting layer (4) 10 to 1000 Å, preferably 50 to 600 Å, second electron-transporting layer (5) 50 to 1000 Å, preferably 200 to 800 Å, electrically n-doped layer 50 to 1000 Å, preferably 100 to 800 Å, electrically p-doped layer 50 to 1000 Å, preferably 100 to 800 Å, third hole-transporting layer (3) to to 1000 Å, preferably 200 to 800 Å, third light-emitting layer (4) 10 to 1000 Å, preferably 50 to 600 Å, third electron-transporting layer (5) to 50 to 1000 Å, preferably 200 to 800 Å, cathode (6) 200 to 10 000 Å, preferably 300 to 5000 Å.

In further embodiments of this "stacked device concept", it is also possible to stack only two OLEDs or to stack more than three OLEDs.

In a further embodiment of white OLEDs, the two concepts mentioned for white light generation can also be combined. For example, a single-color OLED (for example blue) can be stacked with a multicolor layered OLED (for example red-green). Further combinations of the two concepts are conceivable and known to those skilled in the art.

The inventive metal-carbene complexes can be used in any of the layers mentioned above in white OLEDs. In a preferred embodiment, it is used in one or more or all light-emitting layer(s) of the OLED(s), in which case the structure of the invention metal-carbene complex is varied as a function of the use of the complex. Suitable and preferred components for the further layers of the OLED(s) are materials suitable as matrix material in the light-emitting layer(s) and preferred matrix materials are likewise specified above.

The present invention also relates to an organic electronic component, preferably an organic light-emitting diode (OLED), organic photovoltaic cell (OPV), organic field-effect transistor (OFET) or light-emitting electrochemical cell (LEEC), comprising at least one inventive metal-carbene complex.

Examples

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The examples which follow, more particularly the methods, materials, conditions, process parameters, apparatus and the like detailed in the examples, are intended to support the present invention, but not to restrict the scope of the present invention. All experiments are carried out in protective gas atmosphere. The percentages and ratios mentioned in the examples below – unless stated otherwise – are % by weight and weight ratios. *Carbene precursor synthesis*

The synthesis of suitable carbene ligand precursors is well documented in literature. Procedures can be found e.g. in Enders et al. (Helvetica Chimica Acta 1996, 79, 61-83), Bielawski et al. (Inorg. Chem. 2009, 48, 6924-6933), US provisional application 61/496646, and WO2005019373.

General procedure for the complexation

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0.8 mmol of the imidazolium salt and 93 mg (0.4 mmol) silver(I) oxide are dissolved in 20 mL dry 1,4-dioxane and stirred for 21 h at room temperature under an argon addition of 10 mL 2-butanone atmosphere. After and 299 mg (0.8 mmol) dichloro(1,5-cyclooctadiene)platinum the reaction mixture is heated and refluxed for 21 h. The solvent is removed and the residue dissolved in 20 mL dry DMF. A 3.2 mmol amount of the diketone and 359 mg (3.2 mmol) of potassium-tert-butanolate are added. The mixture is then stirred for 21 h at room temperature and another 6 h at 100 °C under argon. After filtration the solvent is removed under reduced pressure and the residue washed with water, followed by column chromatography (silica gel KG60) with dichloromethane as eluent.

EM-1 (D-1)

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Following the procedure described above 269 mg of general 1-phenyl-3-methyl-1H-benzo[d]imidazolium iodide and 0.33 ml of acetylacetone were used to obtain 209 mg (0.42 mmol) of the complex (52%). 1 H-NMR (CDCl₃, 300.13 MHz): δ = 7.90 (d, pseudo-t, J = 7.5 Hz, $J_{H,Pt} = 30.4$ Hz, 2H, CH_{arom.}), 7.76 (d, J = 7.8 Hz, 1H, CH_{arom.}), 7.35 (m, 3H, CH_{arom.}), 7.13 (dt, J = 1.3 Hz, J = 7.6 Hz, 1H, CH_{arom.}), 7.03 (dt, J = 1.1 Hz, J = 1.1 7.4 Hz, 1H, CH_{arom.}), 5.52 (s, 1H, CH), 4.26 (s, 3H, CH₃), 2.08 (s, 3H, CH₃), 2.01 (s, 3H, CH₃) ppm. ¹³C-NMR (CDCl₃, 75 MHz): δ = 185.2 (OCCH₃), 160.7 (C_i), 148.1 (C_i), 135.6 (C_i), 131.3 (C_i), 131.2 (C_{arom.}H), 125.3 (C_i), 124.1 (C_{arom.}H), 123.7 (C_{arom.}H), 123.4 (C_{arom.}H), 122.7 (C_{arom.}H), 111.4 (C_{arom.}H), 110.8 (C_{arom.}H), 110.4 (C_{arom.}H), 102.0 (CH), 31.2 (NCH₃), 28.0 (CH₃), 27.9 (CH₃) ppm. M.p.: 177-179 °C. Anal. Calc. for C₁₉H₁₈N₂O₂Pt (501.44 g mol-1): C: 45.51; H: 3.62; N: 5.59. Found: C: 45.48; H: 3.74; N: 5.62 %.

25 Photoluminescence (2% in PMMA matrix): λ_{max} = 454 nm, CIE: (0.20;0.24); QY = 40%.

EM-2 (D-61)

Following the general procedure described above 279 mg of 1-(4-cyanophenyl)-3-isopropyl-1*H*-benzo[*d*]imidazolium tetrafluoroborate and 0.33 ml of acetylacetone were used to obtain 133 mg (0.24 mmol) of the complex (30%). 1H-NMR (CDCl₃, 300.13 MHz): $\delta = 8.18$ (d, pseudo-t, J = 1.7 Hz, $J_{H,Pt} = 28.6$ Hz, 1H, PtCCH_{arom.}), 7.95 (d, J = 7.6 Hz, 1H, CH_{arom.}), 7.70 (d, J = 7.3 Hz, 1H, CH_{arom.}), 7.54 (d, J = 8.2 Hz, 1H, $CH_{arom.}$), 7.46 (dd, J = 1.8 Hz, J = 8.2 Hz, 1H, $CH_{arom.}$), 7.41 (dt, J = 1.3 Hz, J = 7.5 Hz, 1H, $CH_{arom.}$), 7.34 (dt, $J = 1.1 \, Hz$, $J = 7.5 \, Hz$, 1H, $CH_{arom.}$), 6.48 (sept, $J = 7.0 \, Hz$, 1H, CH_3CH), 5.59 (s, 1H, OCCH), 2.13 (s, 3H, CH₃), 2.03 (s, 3H, CH₃), 1.75 (s, 3H, CH₃), 1.73 (s, 3H, CH₃) ppm. ¹³C-NMR (CDCl₃, 75.5 MHz): δ = 185.9 (OC), 185.4 (OC), 159.9 (C_i), 151.6 (C_i), $134.2 \ (\underline{C}H_{arom.}), \ 133.1 \ (\underline{C}_i), \ 132.2 \ (\underline{C}_i), \ 128.8 \ (\underline{C}H_{arom.}), \ 126.8 \ (\underline{C}_i), \ 124.3 \ (\underline{C}H_{arom.}), \ 123.1 \ (\underline{C}_i), \ 124.3 \ (\underline{C}H_{arom.}), \ 124.3 \ ($ (CH_{arom.}), 120.1 (C_i), 113.7 (CH_{arom.}), 111.3 (CH_{arom.}), 111.2 (CH_{arom.}), 106.2 (C_i), 102.3 (CH), 49.5 (CH₃CH), 27.9 (CH₃), 27.8 (CH₃), 21.3 (CH₃), 21.1 (CH₃) ppm. Anal. Calc. for C₂₂H₂₁N₃O₂Pt (554.51 g mol⁻¹): C: 47.65; H: 3.82; N: 7.58.

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Photoluminescence (2% in PMMA matrix): λ_{max} = 444 nm, CIE: (0.16;0.16); QY = 63%

EM-3 (D-102)

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Following the general procedure described above 287 mg of 1,3-diphenyl-1H-benzo[d]imidazolium tetrafluoroborate and 0.33 ml of acetylacetone were used to obtain 241 mg (0.43 mmol) of the complex (53%). ¹H-NMR (CDCl₃, 300.13 MHz): $\delta = 8.04$ (d, J = 8.2 Hz, 1H, CH_{arom.}), 7.92 (dd, pseudo-t, J = 1.4 Hz, J = 7.4 Hz, $J_{H,Pt} =$ 27.0 Hz, 1H, PtCCH_{arom.}), 7.57 (m, 6H, CH_{arom.}), 7.41 (t, J = 7.8 Hz, 1H, CH_{arom.}), 7.27 (t, J = 7.7 Hz, 1H, CH_{arom.}), 7.19 (dt, J = 1.4 Hz, J = 7.6 Hz, 1H, CH_{arom.}), 7.12 (d, J = 7.40 Hz, 1H, $CH_{arom.}$), 7.09 (dt, J = 1.4 Hz, J = 7.6 Hz, 1H, $CH_{arom.}$), 5.31 (s, 1H, CH), 2.01 (s, 3H, CH_3), 1.31 (s, 3H, CH₃) ppm. ¹³C-NMR (CDCl₃, 125.8 MHz): δ = 185.36 (OCCH₃), 184.09 (OCCH₃), 148.03 (C_i), 136.52 (C_i), 136.23 (C_i), 131.49 (C_{arom.}H), 131.04 (C_i), 129.18 (C_{arom.}H), 129.09 (C_{arom.}H), 128.42 (C_{arom.}H), 126.24 (C_i), 124.48 (C_{arom.}H), 123.82 (C_{arom.}H), 123.75 (C_{arom.}H), 123.10 (C_{arom.}H), 111.81 (C_{arom.}H), 111.55 (C_{arom.}H), 110.93 (C_{arom.}H), 101.71 (CH), 27.56 (CH₃), 27.12 (CH₃) ppm. M.p.: 231-233 °C. Anal. Calc. for C₂₄H₂₀N₂O₂Pt (563.51 g mol⁻¹): C: 51.15; H: 3.58; N: 4.97. Found: C: 51.38; H: 3.63; N: 4.87 %.

Photoluminescence (2% in PMMA matrix): λ_{max} = 457 nm, CIE: (0.16;0.15); QY = 41%.

EM-4 (D-112)

general Following 287 mg of the procedure described above 1,3-diphenyl-1*H*-benzo[*d*|imidazolium 0.67 ml tetrafluoroborate and of 2,2,6,6-Tetramethyl-3,5-heptanedione were used to obtain 210 mg (0.34 mmol) of the complex (40%). ¹H-NMR (CDCl₃, 300.13 MHz): $\delta = 8.05$ (m, 2H, CH_{arom.}), 7.69 (m, 2H, $CH_{arom.}$), 7.60 (m, 3H, $CH_{arom.}$), 7.51 (m, 1H, $CH_{arom.}$), 7.40 (m, 1H, $CH_{arom.}$), 7.23 (d, J =7.3 Hz, 1H, CH_{arom.}), 7.19 (dt, J = 1.9 Hz, J = 7.6 Hz, 1H, CH_{arom.}), 7.10 (dt, J = 1.2 Hz, J = 1.0 H = 7.4 Hz, 1H, CH_{arom.}), 7.05 (d, J = 8.1 Hz, 1H, CH_{arom.}), 5.70 (s, 1H, CH), 1.27 (s, 9H, CH_3), 0.69 (s, 9H, CH_3) ppm. M.p.: 271-275 °C. Anal. Calc. for $C_{30}H_{32}N_2O_2Pt$ (647.67 g mol-1): C: 55.63; H: 4.98; N: 4.33. Found: C: 55.82; H: 4.86; N: 4.19 %. Photoluminescence (2% in PMMA matrix): λ_{max} = 461 nm, CIE: (0.16;0.16); QY = 54%.

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EM-5 (D-122)

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287 mg Following the general procedure described above of 1,3-diphenyl-1*H*-benzo[*d*|imidazolium tetrafluoroborate 732 ma and of 1,3-Diphenyl-1,3-propandione were used to obtain 220 mg (0.32 mmol) of the complex (40%). ¹H-NMR (CDCI₃, 300.13 MHz): δ = 8.15 (dd, *pseudo*-t, J = 1.6 Hz, J = 7.2 Hz, J_{H,Pt} = 26.1 Hz, 1H, PtCCH_{arom.}), 8.10 (dd, J = 1.4 Hz, J = 8.0 Hz, 2H, CH_{arom.}), 8.05 (d, J =8.2 Hz, 1H, $CH_{arom.}$), 7.73 (d, J = 7.9 Hz, 2H, $CH_{arom.}$), 7.64 (d, J = 7.6 Hz, 1H, $CH_{arom.}$), 7.46 (m, 8H, CH_{arom.}), 7.17 (m, 8H, CH_{arom.}), 6.66 (s, 1H, CH) ppm. ¹³C-NMR (CDCl₃, 75.5 MHz): $\delta = 180.4 \text{ (OCC)}, 178.9 \text{ (OCC)}, 160.7 \text{ (C}_i), 148.0 \text{ (C}_i), 139.9 \text{ (C}_i), 136.5 \text{ (C}_i), 136.2 \text{ (C}_i),$ 131.6 (C_{arom.}H), 131.1 (C_{arom.}H), 130.7 (C_{arom.}H), 130.3 (C_{arom.}H), 129.5 (C_{arom.}H), 129.4 (Carom.H), 128.5 (Carom.H), 128.0 (Carom.H), 127.8 (Carom.H), 127.2 (Carom.H), 127.2 (Carom.H), 125.9 (C_i), 124.7 (C_{arom.}H), 124.0 (C_{arom.}H), 123.9 (C_{arom.}H), 123.2 (C_{arom.}H), 112.0 (C_{arom.}H), 111.7 (C_{arom.}H), 111.0 (C_{arom.}H), 96.8 (CH) ppm. M.p.: 234-236 °C. Anal. Calc. for C₃₄H₂₄N₂O₂Pt (687.66 g mol⁻¹): C: 59.39; H: 3.52; N: 4.07. Found: C: 59.30; H: 3.26; N: 4.07 %.

Photoluminescence (2% in PMMA matrix): $\lambda_{max} = 520$ nm, CIE: (0.30;0.56); QY = 78%.

EM-6 (D-142)

Following general procedure described 287 ma of the above 1,3-diphenyl-1*H*-benzo[*d*|imidazolium tetrafluoroborate and 987 mg of dimesitoylmethane were used to obtain 256 mg (0.33 mmol) of the complex (41%). ¹H-NMR (DMSO-d₆, 600.13 MHz): $\delta = 8.38$ (d, J = 8.3 Hz, 1H, CH_{arom.}), 7.84 (d, J = 7.3 Hz, 1H, CH_{arom.}), 7.52 (dt, J = 1.3 Hz, J = 7.5 Hz, 1H, CH_{arom.}), 7.48 (dd, J = 1.0 Hz, J = 8.3 Hz, 3H, CH_{arom.}), 7.36 $(t, J = 7.8 \text{ Hz}, 1\text{H}, CH_{arom.}), 7.15 (dt, J = 1.4 \text{ Hz}, J = 7.7 \text{ Hz}, 1\text{H}, CH_{arom.}), 7.06 (d, J = 8.1 \text{ Hz}, 1.4 \text{ Hz})$ 1H, CH_{arom.}), 7.01 (t, J = 7.9 Hz, 2H, CH_{arom.}), 6.95 (dt, J = 0.9 Hz, J = 7.4 Hz, 1H, CH_{arom.}), 6.87 (s, 2H, $CH_{arom.}$), 6.78 (s, 2H, $CH_{arom.}$), 6.59 (t, $J = 7.5 \, Hz$, 1H, $CH_{arom.}$), 5.34 (s, 1H, CH), 2.30 (s, 3H, CH₃), 2.23 (s, 3H, CH₃), 2.21 (s, 6H, CH₃), 1.95 (s, 6H, CH₃) ppm. ¹³C-NMR (DMSO- d_6 , 125.8 MHz): δ = 185.6 (OCC), 182.6 (OCC), 159.6 (C_i), 147.4 (C_i), 138.6 (C_i), 138.5 (C_i), 137.2 (C_i), 136.3 (C_i), 135.9 (C_i), 134.7 (C_i), 133.2 (C_i), 132.2 (C_i), 130.6 (C_{arom.}H), 129.9 (C_i), 128.3 (C_{arom.}H), 128.1 (C_{arom.}H), 128.0 (C_{arom.}H), 127.3 (C_{arom.}H), 127.2 (C_{arom.}H), 126.2 (C_i), 124.8 (C_{arom.}H), 124.0 (C_{arom.}H), 123.8 (C_{arom.}H), 123.4 (C_{arom.}H), 112.2 (C_{arom.}H), 111.5 (C_{arom.}H), 111.3 (C_{arom.}H), 105.6 (CH), 20.7 (CH₃), 20.6 (CH₃), 19.3 (CH₃), 18.6 (CH₃) ppm. M.p.: 236-238 °C. Anal. Calc. for C₄₀H₃₆N₂O₂Pt (771.81 g mol⁻¹): C: 62.25; H: 4.70; N: 3.63. Found: C: 62.28; H: 4.79; N: 3.72 %.

20 Photoluminescence (2% in PMMA matrix): λ_{max} = 473 nm, CIE: (0.18;0.26); QY = 82%.

EM-7

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Following the general procedure described above 292 mg of 3-benzyl-1-phenyl-1*H*-benzo[*d*]imidazolium bromide and 0.33 ml of acetylacetone were used to obtain 360 mg (0.62 mmol) of the complex (78%). 1 H-NMR (CDCl₃, 300.13 MHz): δ = 7.94 (dd, *pseudo*-t, *J* = 1.3 Hz, *J* = 7.4 Hz, $J_{H,Pt}$ = 28.5 Hz, 1H, PtCC $\underline{H}_{arom.}$), 7.93 (d, *J* = 8.1 Hz, 1H, C $\underline{H}_{arom.}$), 7.52 (dd, *J* = 1.1 Hz, *J* = 7.9 Hz, 1H, C $\underline{H}_{arom.}$), 7.49 (d, *J* = 6.7 Hz, 2H, C $\underline{H}_{arom.}$), 7.31 (m, 5H, C $\underline{H}_{arom.}$), 7.23 (m, 1H, C $\underline{H}_{arom.}$), 7.17 (dt, *J* = 1.4 Hz, *J* = 7.5 Hz, 1H,

 $C_{\underline{H}arom.}$), 7.07 (dt, J = 1.4 Hz, J = 7.5 Hz, 1H, $C_{\underline{H}arom.}$), 6.11 (s, 2H, $C_{\underline{H}2}$), 5.50 (s, 1H, $C_{\underline{H}}$), 2.09 (s, 3H, $C_{\underline{H}3}$), 1.78 (s, 3H, $C_{\underline{H}3}$) ppm. ¹³C-NMR (CDCl₃, 125.8 MHz): δ = 185.5 (OCCH₃), 185.4 (OCCH₃), 160.9 (C_{i}), 148.1 (C_{i}), 136.1 (C_{i}), 134.7 (C_{i}), 131.6 (C_{i}), 131.3 ($C_{arom.}$ H), 128.6 ($C_{arom.}$ H), 127.6 ($C_{arom.}$ H), 127.5 ($C_{arom.}$ H), 125.5 (C_{i}), 124.2 ($C_{arom.}$ H), 123.9 ($C_{arom.}$ H), 111.6 ($C_{arom.}$ H), 111.3 ($C_{arom.}$ H), 111.0 ($C_{arom.}$ H), 102.1 (C_{i} H), 48.5 (C_{i} H₂), 27.9 (C_{i} H₃), 27.7 (C_{i} H₃) ppm. M.p.: 241-244 °C. Anal. Calc. for C_{25} H₂₂N₂O₂Pt (577.54 g mol⁻¹): C: 51.99; H: 3.84; N: 4.85. Found: C: 52.26; H: 3.71; N: 4.71 %.

Photoluminescence (2% in PMMA matrix): λ_{max} = 454 nm, CIE: (0.18;0.20); QY = 53%.

EM-8

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of **Following** the general procedure described above 315 mg 3-benzyl-5,6-dimethyl-1-phenyl-1*H*-benzo[*d*]imidazolium bromide 0.33 ml acetylacetone were used to obtain 319 mg (0.53 mmol) of the complex (66%). 1H-NMR (CDCl₃, 600.13 MHz): $\delta = 7.92$ (dd, pseudo-t, J = 1.3 Hz, J = 7.4 Hz, $J_{H,Pt} = 35$ Hz, 1H, $CH_{arom.}$), 7.66 (s, 1H, $CH_{arom.}$), 7.48 (dd, J = 0.8 Hz, J = 7.7 Hz, 1H, $CH_{arom.}$), 7.44 (d, J =7.3 Hz, 2H, CH_{arom.}), 7.28 (t, J = 7.5 Hz, 2H, CH_{arom.}), 7.23 (t, J = 7.3 Hz, 1H, CH_{arom.}), 7.15 $(dt, J = 1.3 \text{ Hz}, J = 7.5 \text{ Hz}, 1\text{H}, CH_{arom.}), 7.05 (dt, J = 1.3 \text{ Hz}, J = 7.5 \text{ Hz}, 1\text{H}, CH_{arom.}), 7.02$ (s, 1H, CH_{arom.}), 6.01 (s, 2H, CH₂), 5.47 (s, 1H, CH), 2.38 (s, 3H, CH₃), 2.27 (s, 3H, CH₃), 2.07 (s, 3H, CH₃), 1.75 (s, 3H, CH₃) ppm. 13 C-NMR (CDCl₃, 125.8 MHz): δ = 185.3 (OCCH₃), 185.2 (OCCH₃), 159.5 (C_i), 148.3 (C_i), 136.5 (C_i), 133.1 (C_i), 131.8 (C_i), 131.2 (C_{arom.}H), 130.1 (C_i), 128.5 (C_{arom.}H), 127.4 (C_{arom.}H), 127.3 (C_{arom.}H), 125.5 (C_i), 123.7 (C_{arom.}H), 123.3 (C_{arom.}H), 111.6 (C_{arom.}H), 111.5 (C_{arom.}H), 111.4 (C_{arom.}H), 102.0 (CH), 48.3 (CH₂), 27.8 (CH₃), 27.7 (CH₃), 20.4 (CH₃), 20.3 (CH₃) ppm. M.p.: 301-303 °C. Anal. Calc. for C₂₇H₂₆N₂O₂Pt (605.59 g mol⁻¹): C: 53.55; H: 4.33; N: 4.63. Found: C: 53.51; H: 4.50; N: 4.58 %.

Photoluminescence (2% in PMMA matrix): λ_{max} = 457 nm, CIE: (0.17;0.16); QY = 47%.

30 EM-9

Following the general procedure described above 291 mg of 3,5,6-trimethyl-1-phenyl-1*H*-benzo[*d*]imidazolium iodide and 0.33 ml of acetylacetone were used to obtain 285 mg (0.54 mmol) of the complex (67%). 1H-NMR (CDCI₃, 600.13 MHz): $\delta = 8.05$ (s, 1H, CH_{arom.}), 7.70 (d, J = 7.5 Hz, 1H, CH_{arom.}), 7.68 (dd, J = 1.3 Hz, J = 7.5 Hz, 1H, CH_{arom.}), 7.50 (s, 1H, CH_{arom.}), 7.10 (dt, J = 1.3 Hz, J = 7.5 Hz, 1H, CH_{arom.}), 6.93 (dt, J = 1.3 Hz, J = 1.3= 1.3 Hz, J = 7.5 Hz, 1H, CH_{arom.}), 5.64 (s, 1H, CH), 4.23 (s, 3H, NCH₃), 2.43 (s, 3H, CH₃), 2.37 (s, 3H, CH₃), 2.03 (s, 3H, CH₃), 2.01 (s, 3H, CH₃) ppm. M.p.: 261-263 °C. Anal. Calc. for C₂₁H₂₂N₂O₂Pt (529.50 g mol-1): C: 47.64; H: 4.19; N: 5.29. Found: C: 47.26; H: 4.06; N: 5.21 %.

10 Photoluminescence (2% in PMMA matrix): λ_{max} = 455 nm, CIE: (0.18;0.18); QY = 31%.

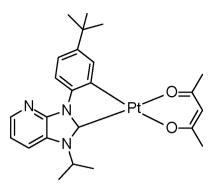
EM-10

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Following the general procedure described above 292 mg of 3-benzyl-1-phenyl-1*H*-benzo[*d*]imidazolium bromide and 987 mg of dimesitoylmethane 15 were used to obtain 399 mg (0.51 mmol) of the complex (64%). 1H-NMR (CDCl₃, 600.13 MHz): $\delta = 7.99$ (d, J = 8.2 Hz, 1H, CH_{arom}), 7.87 (dd, J = 1.3 Hz, J = 7.5 Hz, 1H, $CH_{arom.}$), 7.56 (dd, J = 0.8 Hz, J = 7.8 Hz, 1H, $CH_{arom.}$), 7.36 (t, J = 7.7 Hz, 1H, $CH_{arom.}$), 7.29 (d, J = 7.7 Hz, 1H, CH_{arom.}), 7.24 (t, J = 7.7 Hz, 1H, CH_{arom.}), 7.16 (m, 4H, CH_{arom.}), 7.08 (dd, J = 1.4 Hz, J = 7.9 Hz, 2H, CH_{arom.}), 6.99 (dt, J = 1.3 Hz, J = 7.5 Hz, 1H, CH_{arom.}), 20 6.87 (s, 2H, CH_{arom.}), 6.74 (s, 2H, CH_{arom.}), 5.99 (s, 2H, CH₂), 5.68 (s, 1H, CH), 2.36 (s, 6H, CH₃), 2.31 (s, 3H, CH₃), 2.27 (s, 3H, CH₃), 2.06 (s, 6H, CH₃) ppm. ¹³C-NMR (CDCl₃, 125.8 MHz): δ = 185.7 (OCC), 184.8 (OCC), 160.8 (C_i), 148.1 (C_i), 139.4 (C_i), 139.1 (C_i), 137.7 (C_i), 137.2 (C_i), 136.1 (C_i), 134.9 (C_i), 134.2 (C_i), 133.5 (C_i), 131.8 (CH_{arom.}), 131.5 25 (Ci), 128.4 (CH_{arom.}), 128.2 (CH_{arom.}), 127.8 (CH_{arom.}), 127.2 (CH_{arom.}), 126.6 (CH_{arom.}), 125.1 (C_i), 124.3 (CH_{arom.}), 124.1 (CH_{arom.}), 123.7 (CH_{arom.}), 123.0 (CH_{arom.}), 111.7 (CH_{arom.}), 111.4 (CH_{arom.}), 111.0 (CH_{arom.}), 107.0 (CH), 48.1 (CH₂), 21.2 (CH₃), 21.1 (CH₃), 20.0 (CH₃), 19.1 (CH₃) ppm. M.p.: 144-145 °C. Anal. Calc. for C₄₁H₃₈N₂O₂Pt (785.85 g mol⁻¹): C: 62.67; H: 4.87; N: 3.56. Found: C: 62.66; H: 4.70; N: 3.60 %.

30 Photoluminescence (2% in PMMA matrix): λ_{max} = 476 nm, CIE: (0.18;0.27); QY = 85%.

EM-11 (E-57)



Following the general procedure described above 423 mg of 1-((4-*tert*butyl)phenyl)-3-isopropyl-1*H*-(azabenzo)[*d*]imidazolium iodide and 0.33 ml of acetylacetone were used to obtain 42 mg (0.07 mmol) of the complex (10%). ¹H-NMR (CD₂Cl₂, 400 MHz MHz): δ = 8.42 (d, *J* = 5.9 Hz, 1H.), 8.18 (d, *J* = 8.4 Hz, 1H), 7.93 (d, *J* = 8.2 Hz, 1H), 7.86 (s, 1H), 7.21-7.26 (m, 1H), 7.14-7.18 (m, 1H), 6.37 (sept, *J* = 7.2 Hz, 1H), 5.59 (s, 1H), 2.10 (s, 3H), 2.02 (s, 3H), 1.70 (d, *J* = 7.0 Hz, 6H) ppm.

Photoluminescence (2% in PMMA matrix): λ_{max} = 465 nm, CIE: (0.16;0.17); QY = 46%.

Dependency of CIE color coordinates and photoluminescence quantum efficiency (PLQE) from doping concentration

Films of EM-6 in PMMA with varying concentrations of **EM-6** are prepared to evaluate the color and PLQE stability at different concentrations.

Amount of EM-6 in EML [%]	1	3	6	10
CIE (x;y)	0.18; 0.26	0.18; 0.27	0.18; 0.29	0.19; 0.30
PLQE [%]	82	86	83	83

This experiment clearly demonstrates the low sensitivity of CIE color coordinates and PLQE towards a variation of the concentration of the inventive emissive compounds.

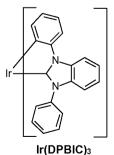
Application Example 1

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The ITO substrate used as the anode is cleaned first with commercial detergents for LCD production (Deconex® 20NS, and 25ORGAN-ACID® neutralizing agent) and then in an acetone/isopropanol mixture in an ultrasound bath. To eliminate possible organic residues, the substrate is exposed to a continuous ozone flow in an ozone oven for a further 25 minutes. This treatment also improves the hole injection properties of the ITO. Next, the hole injection layer AJ20-1000 from Plexcore is spun on from solution.

Thereafter, the organic materials specified below are applied by vapor deposition to the cleaned substrate at about 10-7-10-9 mbar at a rate of approx. 0.5-5 nm/min. The hole

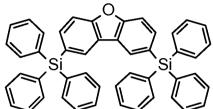


conductor and exciton blocker applied to the substrate is

(for

preparation of $Ir(DPBIC)_3$ see Ir complex (7) in the application WO2005/19373) with a thickness of 20 nm, of which the first 10 nm are doped with MoO_x to improve the conductivity.

5 Subsequently, a mixture of emitter Em6 (30 % by wt.), Ir(DPBIC)₃ (10% by wt.), and



compound (Ma1; 60 % by wt.; compound " 4g" in WO2009/003898) is applied by vapor deposition with a thickness of 40 nm, the latter compounds functioning as matrix materials.

Subsequently, the material **Ma1** is applied by vapor deposition with a thickness of 5 nm as a hole blocker. Next, as an electron transporting layer, a mixture of Cs₂CO₃ (5 % by wt.) and BCP (2,9-dimethyl-4,7-diphenyl-1,10-phenanthroline; 95 % by wt.) is applied by vapor deposition with a thickness of 25 nm and finally a 100 nm-thick Al electrode. All components are adhesive-bonded to a glass lid in an inert nitrogen atmosphere.

Application Example 1

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 λ_{max} = 504 nm, CIE: (0.20; 0.31); U = 6.9 V; EQE (external quantum efficiency is # of generated photons escaped from a substance or a device / # of electrons flowing through it): = 12.6%.

Dependency of CIE color coordinates from doping concentration

Devices according to application example 1 were fabricated with varying emitter concentrations in the emissive layer:

HIL Plexcore AJ20-1000 - 10nm Ir(DPBIC)₃:MoO_x (90:10) - 10nm Ir(DPBIC)₃ - 40nm Em6: Ma1 (X:(100-X)) - 5nm Ma1 - 25nm BCP:Cs₂CO₃ (95:5) - 100nm AI.

By varying the doping concentration of **Em6** from 5% to 30% the influence on the color coordinates of the emitted light was determined.

Amount of EM-6 in EML [%]	5	10	20	30
CIE (x;y)	0.19;0.28	0.19;0.29	0.20;0.31	0.20;0.32

30 As these results clearly demonstrate there is only a minor shift in color coordinates when significantly altering the doping concentration in a range from 5% to 30%. This low concentration dependency is especially important for reproducibility in mass production.

Claims

1. A metal-carbene complex of the general formula

(I), wherein

5 M is Pd or Pt,

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R₁ is a linear or branched alkyl radical optionally interrupted by at least one heteroatom, optionally bearing at least one functional group and having 1 to 20 carbon atoms, substituted or unsubstituted cycloalkyl radical optionally interrupted by at least one heteroatom, optionally bearing at least one functional group and having 3 to 20 carbon atoms, substituted or unsubstituted aryl radical, optionally bearing at least one functional group and having 6 to 30 carbon atoms, substituted or unsubstituted heteroaryl radical optionally interrupted by at least one heteroatom, optionally bearing at least one functional group and having a total of 5 to 18 carbon atoms and/or heteroatoms,

 R_2 and R_2 ' are independently of each other a linear or branched alkyl radical having 1 to 6 carbons atoms, substituted or unsubstituted cycloalkyl radical having 3 to 20 carbon atoms, substituted or unsubstituted aryl radical having 6 to 20 carbon atoms, substituted or unsubstituted heteroaryl radical having a total of 5 to 18 carbon atoms and/or heteroatoms,

 R_3 is hydrogen, a linear or branched alkyl radical having 1 to 6 carbon atoms, substituted or unsubstituted aryl radical having 6 to 20 carbon atoms,

 R_4 and R_5 are independently of each other hydrogen, a linear or branched alkyl radical optionally interrupted by at least one heteroatom, optionally bearing at least one functional group and having 1 to 6 carbon atoms, substituted or unsubstituted cycloalkyl radical optionally interrupted by at least one heteroatom, optionally bearing at least one functional group and having 3 to 12 carbon atoms, substituted or unsubstituted aryl radical optionally interrupted by at least one heteroatom, optionally bearing at least one functional group and having 6 to 15 carbon atoms, substituted or unsubstituted heteroaryl radical optionally interrupted by at least one heteroatom, optionally bearing at least one functional group and having a total of 5 to 18 carbon atoms and/or heteroatoms, group with donor or acceptor action,

A is independently in each occurrence CR₆ or N, with the proviso that at least 3 As are CR₆;

each R_6 is independently of each other hydrogen, a linear or branched alkyl radical optionally interrupted by at least one heteroatom, optionally bearing at least one functional group and having 1 to 20 carbon atoms, substituted or unsubstituted

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cycloalkyl radical optionally interrupted by at least one heteroatom, optionally bearing at least one functional group and having 3 to 20 carbon atoms, substituted or unsubstituted aryl radical optionally interrupted by at least one heteroatom, optionally bearing at least one functional group and having 6 to 30 carbon atoms, substituted or unsubstituted heteroaryl radical optionally interrupted by at least one heteroatom, optionally bearing at least one functional group and having a total of 5 to 18 carbon atoms and/or heteroatoms, group with donor or acceptor action.

2. The metal-carbene complex according to claim 1 of the general formula

$$R_{6}$$
 R_{6}
 R_{1}
 R_{2}
 R_{2}
 R_{2}
 R_{3}

(II), wherein

 $R_{6'}$ and $R_{6''}$ have independently of each other the meaning of R_6 and M, R_1 , R_2 , R_2 ', R_3 , R_4 , R_5 , R_6 and A are each defined as in claim 1.

3. The metal-carbene complex according to claim 2 of the general formula

$$R_{6}$$
 R_{6}
 R_{1}
 R_{2}
 R_{2}
 R_{3}
 R_{4}
 R_{5}

15 (Ila), or

$$R_{6}$$
 R_{6}
 R_{1}
 R_{2}
 R_{2}
 R_{3}

(IIb), wherein M, R_1 , R_2 , R_2 , R_3 , R_4 , R_5 , R_6 ,

 $R_{6'}$, $R_{6''}$ and A are each defined as in claim 2.

- 4. The metal-carbene complex according to any of claims 1 to 3, wherein M is Pt.
- 5. The metal-carbene complex according to any of claims 1 to 4, wherein R₃ is hydrogen, a linear or branched alkyl radical having 1 to 6 carbon atoms.

6. The metal-carbene complex according to any of claims 1 to 5, wherein R₂ and R₂' are independently of each other a linear or branched alkyl radical having 1 to 6 carbon atoms, a substituted or unsubstituted aryl radical having 6 to 20 carbon atoms, substituted or unsubstituted heteroaryl radical having a total of 5 to 18 carbon

10 atoms and/or heteroatoms.

- 7. The metal-carbene complex according to any of claims 1 to 6, wherein R₄ and R₅ are each independently hydrogen, a linear or branched alkyl radical having 1 to 6 carbon atoms, substituted or unsubstituted aryl radical having 6 to 15 carbon atoms, or a group with donor or acceptor action, selected from halogen radicals.
- 8. The metal-carbene complex according to any of claims 1 to 6, wherein R_1 is a linear or branched alkyl radical having 1 to 6 carbons atoms, or unsubstituted aryl radical having 6 to 15 carbon atoms.

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- 9. The metal-carbene complex according to any of claims 1 to 8, wherein R_6 and $R_{6'}$ are hydrogen, or C_1 - C_6 alkyl; and $R_{6''}$ is hydrogen.
- 10. An organic electronic device, comprising at least one metal-carbene complex according to any of claims 1 to 9.
 - 11. The organic electronic device according to claim 10, wherein the organic electronic device is selected from organic light-emitting diodes (OLEDs), organic photovoltaic cells (OPVs), organic field-effect transistors (OFETs) and light-emitting electrochemical cells (LEECs).
 - 12. A light-emitting layer comprising at least one metal-carbene complex according to any of claims 1 to 9.
- 35 13. The light-emitting layer according to claim 12, comprising at least one metal-carbene complex according to any of claims 1 to 9 and a host material.
- An apparatus selected from the group consisting of stationary visual display units such as visual display units of computers, televisions, visual display units in printers,
 kitchen appliances and advertising panels, illuminations, information panels, and mobile visual display units such as visual display units in cellphones, tablet PCs, laptops, digital cameras, MP3 players, vehicles and destination displays on buses and trains; illumination units; keyboards; items of clothing; furniture; wallpaper,

comprising the organic electronic device according to claim 10, or 11, or the emitting layer according to claim 12, or 13.

- 15. Use of metal-carbene complex according to any of claims 1 to 9 for electrophotographic photoreceptors, photoelectric converters, organic solar cells (organic photovoltaics), switching elements, organic light emitting field effect transistors (OLEFETs), image sensors, dye lasers and electroluminescent devices.
- 16. A process for preparing the metal-carbene complexes according to claim 1 by contacting suitable compounds comprising M with compounds of the general

$$A = A \qquad \qquad \begin{array}{c} R_1 \\ N \\ X \end{array}$$

$$R_4 \qquad \qquad \begin{array}{c} R_1 \\ N \\ R_5 \end{array}$$

formula

(IV), wherein

 R_1 , R_4 , R_5 and A are each as defined in claim 1 and X is F, Cl, Br, I, PF₆, or BF₄.

INTERNATIONAL SEARCH REPORT

International application No.

PCT/IB2013/056434

		1 C1/ 1D2019/ 000494
A. CLASSIFICATION OF SUBJECT MATTER		
	extra sheet	
According to International Patent Classification (IPC) or to both na	ational classification and IPC	
B. FIELDS SEARCHED		
Minimum documentation searched (classification system followed	by classification symbols)	
IPC: C07F 1	5/-; H01L 51/-	
Documentation searched other than minimum documentation to the	e extent that such documents are	included in the fields searched
Electronic data base consulted during the international search (nan	ne of data base and, where practic	cable, search terms used)
WPI, EPODOC, CNKI, CNPAT, STN, CA: BASF, carbene, metal, p	alladium, platinum, complex, ac	etylacetonate, ligand, OLED, Pt, Pd
C. DOCUMENTS CONSIDERED TO BE RELEVANT		
Category* Citation of document, with indication, where a	ppropriate, of the relevant passag	ges Relevant to claim No.
X US 2009018330 A1 (BASF SE) 15 January 2009 (15.	.01.2009)	1-16
description, paragraphs [0002]-[0003], [0010]-[0019]		4]
A US 2006287544 A1 (PROMERUS LLC) 21 December	er 2006 (21.12.2006)	1-16
description, paragraphs [0004]-[0056]		
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Special categories of cited documents:		l after the international filing date
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Date of the actual completion of the international search	Date of mailing of the international search report	
02 December 2013 (02.12.2013)	02 Jan. 20]	14 (02.01.2014)
Name and mailing address of the ISA/CN The State Intellectual Property Office, the P.R.China 5 Xitucheng Rd., Jimen Bridge, Haidian District, Beijing, China	Authorized officer GAO), Xiaowei
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INTERNATIONAL SEARCH REPORT

International application No.

PCT/IB2013/056434

Continuation of A. CLASSIFICATION OF SUBJECT MATTER:
C07F 15/00 (2006.01) i
H01L 51/50 (2006.01) i
H01L 51/00 (2006.01) i

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INTERNATIONAL SEARCH REPORT

Information on patent family members

International application No.
PCT/IB2013/056434

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